



B V C INSTITUTE OF TECHNOLOGY & SCIENCE :: BATLAPALEM

MID EXAM - II

II B TECH II SEM CIVIL

SUB: E E

TIME: 9.30 to 11.00 a. m

DATE: 19.04.24


MAX MARKS: 15

ANSWER ALL THE QUESTIONS.

3 X 5 = 15

1. Water main appurtenances and explain about few important ones? (C224.3 Remembering)
2. Design aspects of sewers and types of sewers? (C224.4 Understanding)
3. Explain about disposal methods of sewage? (C224.5 Applying)




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BONAM VENKATA CHALAMAYYA INSTITUTE OF TECHNOLOGY AND SCIENCE
DEPARTMENT OF CIVIL ENGINEERING
ENVIRONMENTAL ENGINEERING

Scheme of Evaluation With CO and BT Mapping

Course: Environmental Engineering (C224)

Class: II B. Tech II Sem

AY: 2023 -24

SCHEME OF EVALUATION WITH CO AND BT MAPPING

SNO	QUESTION	CO	BT
1	Water main appurtenances and explain about few important ones?	C224.3	Remembering
2	Design aspects of sewers and types of sewers?	C224.4	Understanding
3	Explain about disposal methods of sewage?	C224.5	Applying

1. Water main appurtenances and explain about few important ones


Appurtenances 3M
Explanation 2M

2. Design aspects of sewers and types of sewers

Design 2M
Types 3M

3. Explain about disposal methods of sewage

Explanation 5M


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Faculty signature

BONAM VENKATA CHALAMAYYA INSTITUTE OF TECHNOLOGY & SCIENCE
Department of Civil Engineering

A.Y: 2023-24

Course: Environmental Engineering

Branch: Civil Engineering

Max Marks: 15

Duration: 1 Hr 30 min

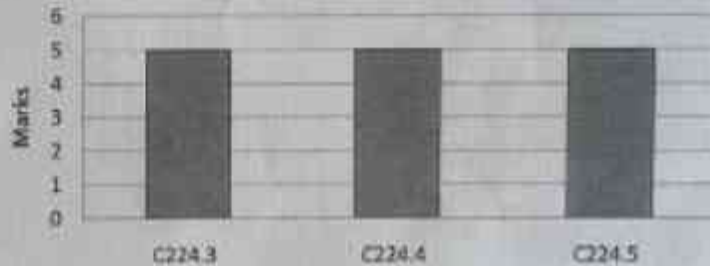
Q.No	Questions	Marks	CO	BL
1	Water main appurtenances and explain about few important ones?	5	C224.3	L1
2	Design aspects of sewers and types of sewers	5	C224.4	L2
3	Explain about disposal methods of sewage	5	C224.5	L3

Blooms level marks distribution

■ L1 ■ L2 ■ L3



Course Outcome wise Mark Distribution




Course outcomes wise percentage coverage

■ L1 ■ L2 ■ L3



BL - Bloom's Taxonomy Levels (L1- Remembering, L2- Understanding, L3- Applying, L4- Analysing, L5- Evaluating, L6- Creating)


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1.
Ans:Sewer Appurtenances:

The following are the main and important types of the sewer appurtenances. They are:

- * Manhole
- * Clean out
- * Regulators
- * Catch-basin
- * Inlet
- * Lamp hole
- * Drop backhole
- * flashhole

Let us briefly discuss about the above following appurtenances

* Manhole:

Manhole is a structure which is constructed to provide the access for the facilitating the inspections, cleaning and manufacturing of the operations.

• Objectives:

- ⇒ The manholes are used for cleaning and manufacturing the sewers.
- ⇒ The obstacles present in the manhole it is collected and brought upto the surface of the ground.
- ⇒ The joining and changing of the sewer lines.
- ⇒ The sewers caseries of different lines with various direction
- ⇒ The convenient length of the underground pipes are also taken
- ⇒ The flow of water and the obstacles can be controlled by the manhole.

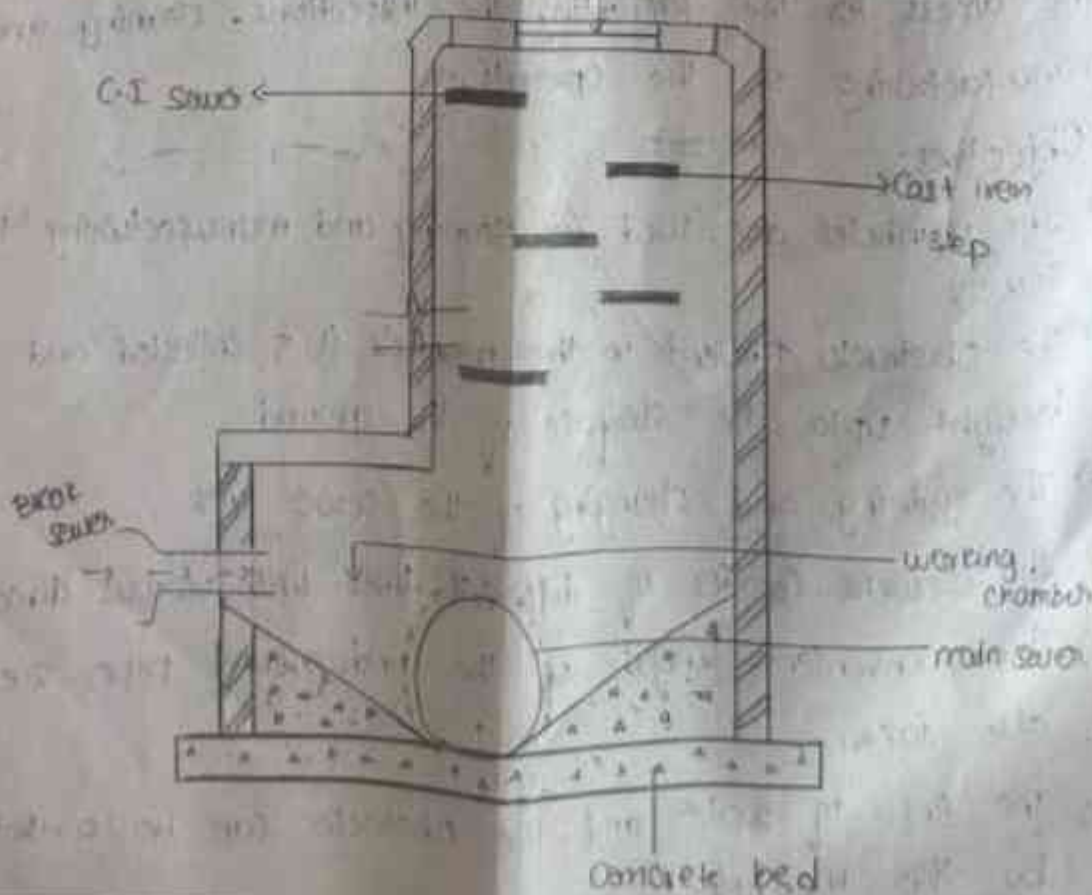
Requirements:-

- Inside the pipe the pipe should be plastered.
- The floor & wall should be impervious.
- The stagnation should be prevented in man hole.
- The safety for the workers to work in.
- The load should be sufficient.

Parts of manhole:

Manhole is constructed by concrete or RCC chamber. The chamber is covered by the manhole cover on the top & the chamber is fitted to the cast iron. The following are the main parts of man hole.

- * An access shaft
- * Working chamber
- * Strong cover on top
- * Ladder or steps



* Clean out:

The pipes which are connected to the lateral sewer the one end of the pipe is brought up to the ground level surface then that system is called as clean out system.

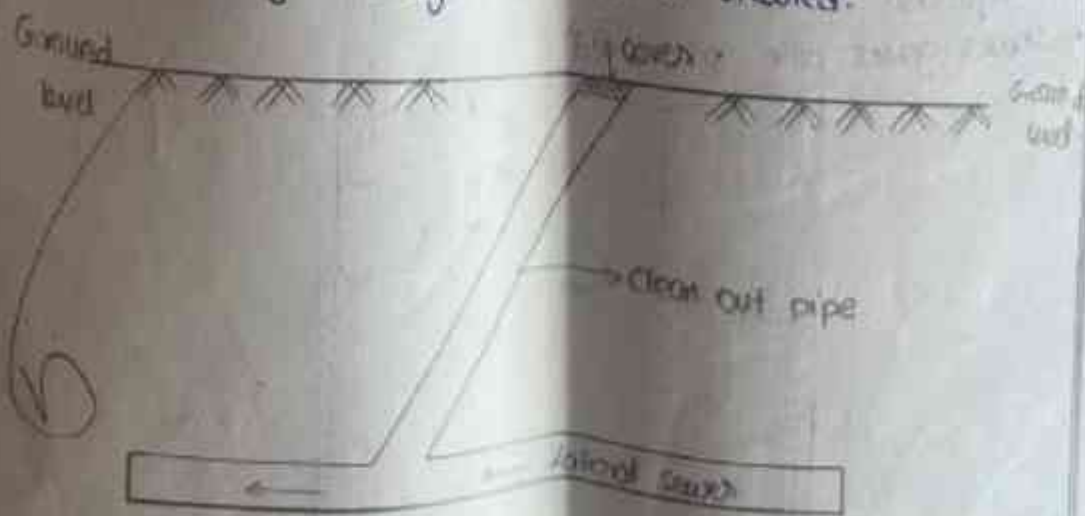
• Location:-

The pipe is placed in the ground and the upper end is placed to the forward. The sewer in the man hole of the placed.

• Working:-

The working of clean out is very simple

- + The lateral sewer is brought up to the ground level surface and the water flows.
- + The cover is taken out and the water is forced to flow.
- + The obstacles which are present in the pipe are eliminated.
- + If the large obstacle is present then a flexible rod is taken and it is inserted into pipe and pushed forward & backward by through this that is cleared.



* Regulators:

The storm water or relief water is cleared through the process of regulators. The storm water is converted and directed

The water is subjected through different sewers present in the sewerage of the system and thus the types of regulating system gives various ways to work.

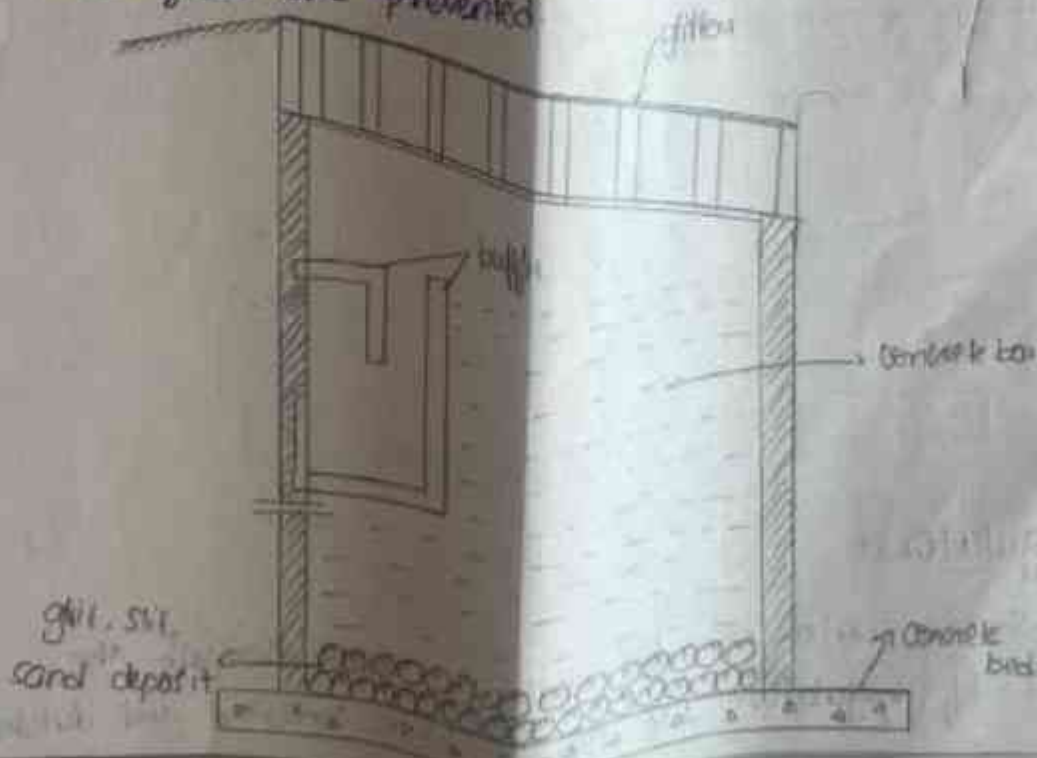
- * Over-flow weir
- * Leaping weir
- * Syphon spill way

* Catch - basin:

The rain water is cleaned and it is recycled to a clean water. The process of catch basin is the it is made up of concrete box & consists of different gills. The difference b/w the gutter & storm water.

Objects:

- The water should be in form of rain water.
- It is passed through lateral sewer.
- sewerages are controlled.
- The rain water is excavated & the waste is separated.
- The impurities are separated.
- The waste matter should be cleaned because of bad smell & mosquitoes.
- sewer gases are prevented.



Name

Class / Course

Date

Regd. No. : 102

Subject

Instructor Sign

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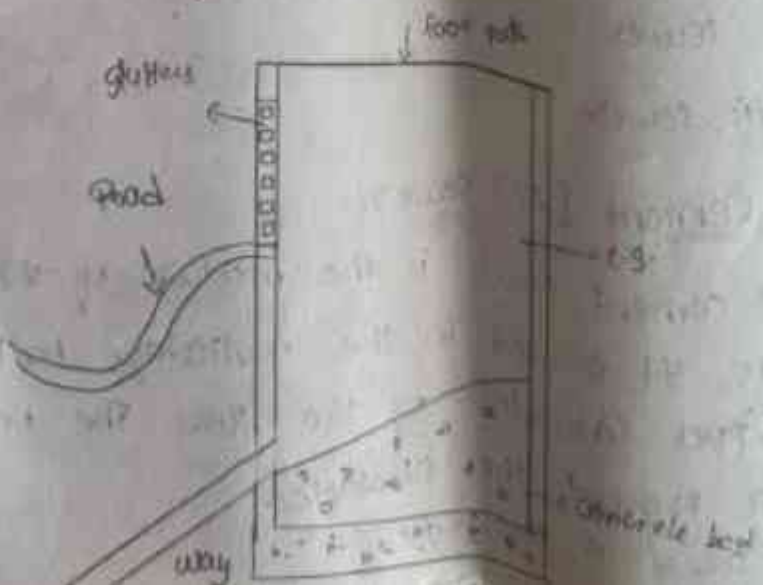
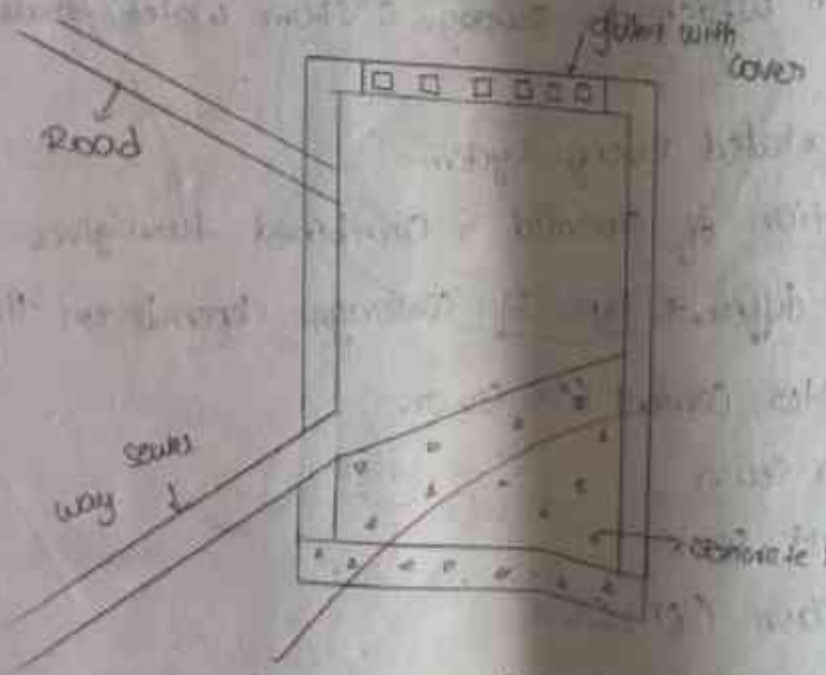
* Inlet:

The inlet is the difference b/w gutter & storm water. The water is carried out in diff ways and horizontal & vertical. The Inlet sewer is the presence and clear out the way of the obstacles meant for the pipes of sewer.

→ Types of Inlet:

- * Horizontal Intake
- * Vertical Intake

- * (a) Road points
- (b) Low pressure



Sewer:

The underground conduit which present in the under surface then it is called as sewer which collects the waste matter & drain off the water. The gravity flow is named. The main flow sewer is called main force flow.

Sewerages:

The art of the treatment of disposal of the sewer. There are 3 types.

① Primarily system:

In this system the flow of stream water & sewerages sanitary flow in the two sets of sewer.

② Combined sewerage system:

The system in which the sewerage & storm water flows in the one set.

③ Partially separated sewerage system:

The combination of separated & combined flow gives the result.

* There are different types of sewerages depends on the material.

* Asbestos cement (AC) sewer.

* Brick sewer.

* Cement sewer.

* Cast iron (CI) sewer.

* Steel sewer.

* Plastic sewer.

* Asbestos Cement [AC] sewer:

The Asbestos cement sewer is the mixture of the cement & asbestos fibre. It is used in the multistage buildings for the high & upper circulation of the flow. The need of this sewer is to prevent the obstacles.

The cement sewer is involved.

Name

Class / Course

Date

Regd. No

Subject

Invigilator Sign

Advantages:

- * Light in weight.
- * Smooth surface
- + Easy to cut off, drill and fitting
- * Soil Consumption.

Disadvantages:

- * Brittle in nature, can be break due to heavy load.
- * Easily can't be transported

* Brick sewer:

The brick sewers are made at the site of construction and used from there. The system involved is combined system. The But now-a-days the brick sewers are not constructed due to leakage of water and thus cement sewers are constructed.

Note:

The bricks which are used should be plastered to prevent the leakages.

- The bricks should be well manufactured.
- It should resist the force.

* Cement sewer:

The cement sewer is the important sewer due to its construction & material mixture.

i) RCC — diameter upto 60cm dia.

The durability is less so that it cannot be used as more depth.

ii) PCC — dia > 60cm of dia.

The compactness of the PCC is good so that it can bear the load & impact load of sewer. The finishes are matted.

Cast Iron sewer:

The CI sewer are most high durable & more effective strength. The impact loads and every load is possible at the sewer. The loads are perfect

Requirements:

- The pressure should be under load.
- The temperature should be maintained.
- The pressure of the pipe are constant.
- The body of the pipe and the pressure is to be constant.

Steel sewers:

The pipes which has more strength they are also more likely as the cast iron sewer. The importance of it.

Plastic sewers:

The PVC is the pipe which is mostly used but due to thermal expansion, the heat is generated & thus the pipe is effected. This pipes may can lead to leakage.

3. Disposal Methods of sewage:

There are mainly 2 types of methods.

- i. Artificial method
- ii. Natural method

i. Artificial method.

- (a) Primary method
- (b) Secondary method

ii. Natural method

- (a) Dilution.
- (b) Land treatment.

Name:

Class / Course:

Date:

Regd. No.: 102

Subject:

Instructor Sign: (a) Dillution:

The water treatment of the waste like seas, lakes, rivers etc treated is called as dillution.

- * The process in which the body are treated due to the water of the presence.
- * The stagnation of the body is treated.
- * The floods occurs by that the dillution is carried out.
- * The process the water from the bodies seas, lakes, rivers etc.
- * The dillution is process in which filtration, recycling, disposal and more techniques are involved.
- * The water undergoes dillution treatment.
- * Dillution treatment is the best treatment for the water stagnation & thus the behaviour of the water will be mainted.
- * The clean water can be obtained.

(b) Land treatment:

- * The land surface which is spreaded over the stagnated water the process carried out is called as land treatment.
- * The land treatment is carried by board irrigation.
- * The filtration of water carries out in the different way.
- * The land waste matter is recycled or converted and it is filtered in the matter.
- * The treatment of water is carried out by the works of the

* The Land treatment is divided into 2 types.

* Filtration.

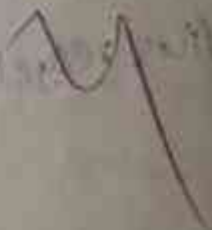
* Band migration.

* The Land which is treated through the process of surface of land.

* The process of the disposal technique is to prevent the obstacles and the process in which the water is treated.

* The treatment of water and the land involves the natural methods of the sewage of techniques.

* The land waste is recycled through different processes.



S No	Regd. No	CVSM		SMII		H&HM		EE		MEFA	
		R2022011		R2022012		R2022013		R2022014		R2022015	
		1mid	2mid	1mid	2mid	1mid	2mid	1mid	2mid	1mid	2mid
		mm 15	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15
1	22H41A0101	12	14	14	13	13	12	14	14	14	13
2	22H41A0102	15	15	15	14	14	15	15	14	14	14
3	22H41A0103	14	14	15	14	14	13	14	14	14	14
4	22H41A0104	15	14	15	13	14	13	14	14	13	14
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7	22H41A0107	15	14	15	13	15	15	15	14	14	15
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25	22H41A0125	10	14	15	13	13	12	14	12	12	12
26	22H41A0126	7	15	10	12	10	9	12	14	10	9

S No	Regd. No	CVSM		SMII		H & HM		EE		M
		R2022011		R2022012		R2022013		R2022014		R2
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54	23H45A0108	6	11	13	13	14	10	14	14	12
55	23H45A0109	10	15	15	13	14	13	13	13	10

BONAM VENKATA CHALAMAYYA INSTITUTE OF TECHNOLOGY & SCIENCE

Department of Electrical & Electronics Engineering

INTERNAL EXAMINATION-1

A.Y: 2023-24

Course: UTILISATION OF ELECTRICAL ENERGY

Branch: EEE

Year: III

Semester: I

Max Marks: 15

Duration: 1 Hr 30 min

Q.No	Questions	Marks	CO	BL
1 a)	Prove that the illumination is proportional to cosine of angle made by the normal to the illuminated surface with the direction of incident flux	2.5	C3152.1	L3
1 b)	A lamp giving out 1010 m in all directions is suspended 7m above the working plane. Find the illumination at a point on the working plane 5m away from the foot of the lamp	2.5	C3152.1	L4
2 a)	Elaborate the electrical characteristics of a motor used for the electrical drive?	2.5	C3152.2	L1
2b)	A 450V series motor having armature and field resistances of 0.28 ohms and 0.32 ohms runs at 540 r.p.m when taking 72A. Assuming un saturated field find out its speed when field diverter of 0.872 ohms is used for the loads whose torque remains constant and varies as square of the speed	2.5	C3152.2	L4
3 a)	Elaborate the meritorious advantages of electrical heating process?	2.5	C3152.3	L4
3 b)	Compare the features of direct and in direct core type induction furnaces?	2.5	C3152.3	L4

BLOOMS LEVEL WISE MARKS DISTRIBUTION



• C3152.3 • C3152.5 • C3152.6

COURSE OUTCOME WISE MARKS DISTRIBUTION



BL – Bloom's Taxonomy Levels (L1- Remembering, L2- Understanding, L3 – Applying, L4 – Analysing, L5 – Evaluating, L6 - Creating)

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Bonam Venkata Chalamayya Institute of Technology & Science
Department of Electrical and Electronics Engineering
Scheme of Evaluation with CO and BT Mapping

Course: **UTILISATION OF ELECTRICAL ENERGY (C3152)**
 Class: III B.Tech 1st semester
 AY: 2023-24

SCHEME OF EVALUATION WITH CO AND BT MAPPING

SNO	QUESTION	CO	BT
1 a)	Prove that the illumination is proportional to the cosine of the angle made by the normal to the illuminated surface with the direction of incident flux.	C3152.1	Applying
1 b)	A lamp giving out 1010 m in all directions is suspended 7m above the working plane. Find the illumination at a point on the working plane 5m away from the foot of the lamp ?	C3152.1	Analyzing
2 a)	Elaborate the electrical characteristics of a motor used for the electrical drive?	C3152.2	Remembering
2 b)	A 450V series motor having armature and field resistances of 0.28 ohms and 0.32 ohms runs at 540 r.p.m when taking 72A. Assuming un saturated field find out its speed when field diverter of 0.872 ohms is used for the loads whose torque remains constant and varies as square of the speed?	C3152.2	Analyzing
3 a)	Elaborate the meritorious advantages of electrical heating process?	C3152.3	Analyzing
3 b)	Compare the features of direct and in direct core type induction furnaces?	C3152.3	Analyzing

1 a) Statement & Diagram-----1M

Derivation of Lamberts Cosine Law -----1.5M

b) Problem -----2.5M

2 a) Electrical Characteristics -----1M

Explanation -----1.5M

b) Problem -----2.5M

3 a) Advantages of Electrical Heating ----2.5M

b) Compare Direct & Indirect core type Furnaces-----2.5M


HOD




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MAIN ANSWER SCRIPT

Name: A. Haritha

Regd. No: BT14110201 Date: 21/12/2021

Subject: UEE

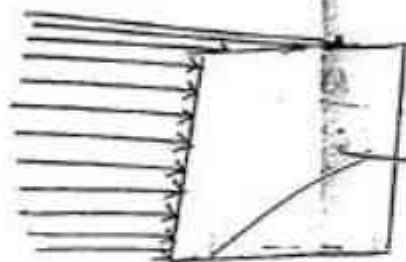
Class / Course: 3rd Btch (EEE) Irrigation Syst

1.(a)

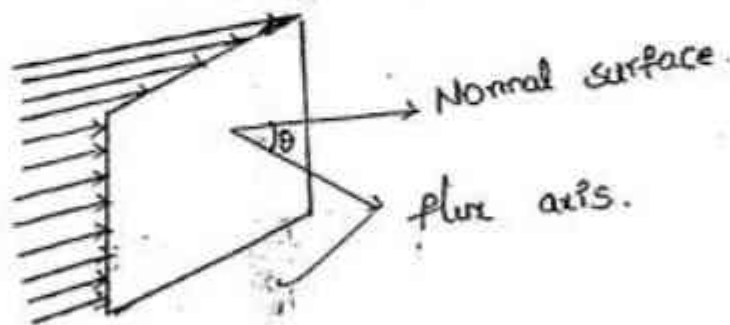
Ans Lambert's cosine law:

The illumination of a plane is proportional to the cosine angle b/w the normal surface to the direction of flux.

$$E \propto \cos \theta$$

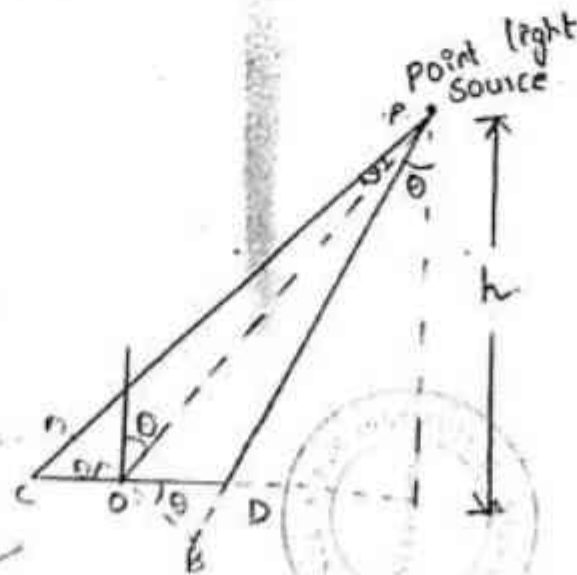


Normal surface made 0° to the flux axis



Normal surface

flux axis.



Let us consider the flux is falling on the surface ABCD with height h and distance r .

Let θ be the angle between the point light source as shown in the figure D.

Let OD is the surface area of CD with angle θ , AB is the surface area of OP with angle w .

$$CD = \frac{AB}{\cos \theta}$$

$$\cos \theta = \frac{AB}{CD}$$

$$E = \frac{I}{r^2} \cos \theta$$

(or)

$$E = \frac{I}{h^2} \cos^3 \theta$$

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Q. (b)
me

Given data,

$$I = 1010 \text{ amperes}$$

$$h = 4 \text{ m}$$

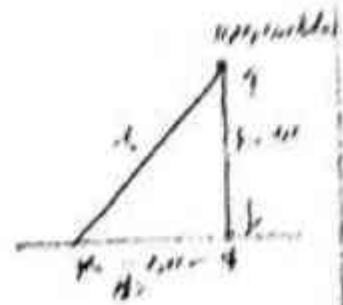
$$d = 5 \text{ m}$$

$$r = \sqrt{h^2 + d^2}$$

$$= \sqrt{(4)^2 + (5)^2}$$

$$= \sqrt{16 + 25}$$

$$r = 8.6 \text{ m}$$



$$\cos \theta = \frac{h}{r} = \frac{4}{8.6} = 0.81$$

from Lambert's cosine law:

$$E = \frac{I}{r^2} \cos \theta$$

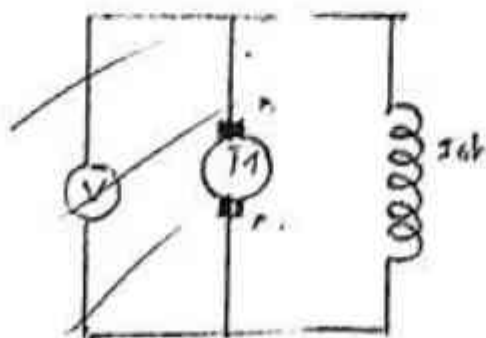
$$= \frac{1010}{(8.6)^2} \times 0.81$$

$$E = 11.06 \text{ LUX}$$

Q. (c)
me

Electrical characteristics:

D.C. shunt motor:



A field winding is connected across the motor armature is called DC shunt motor.

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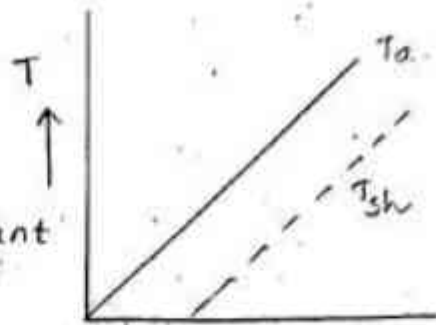
(1) Torque \propto V_s Armature current :

For dc motor, - the expression is.

$$T \propto \phi I_a$$

Where, $\phi = \text{constant}$

$$T \propto I_a$$



Torque is directly proportional $\rightarrow I_a$ to the Armature current.

If load increases the Armature current increases, and torque also increases.

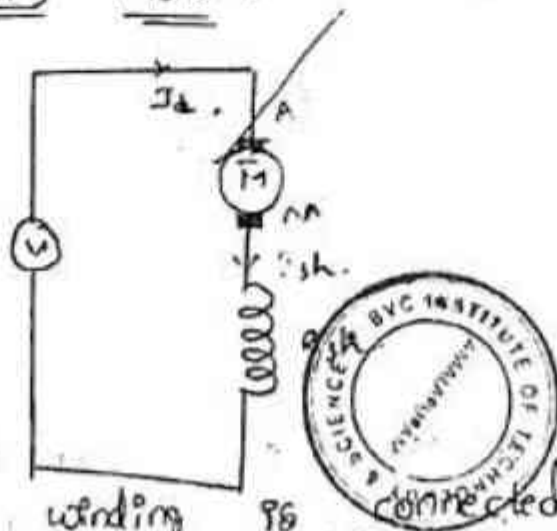
$$\text{load} \uparrow \quad I_a \uparrow \quad T \uparrow$$

The shaft torque T_{sh} is less than the T_a .

$$T_{sh} < T_a$$

Therefore the graph will be a straight line passing through the origin.

2. DC Series Motor :



A field winding is connected with the motor armature is called DC

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Name: A. Hossain

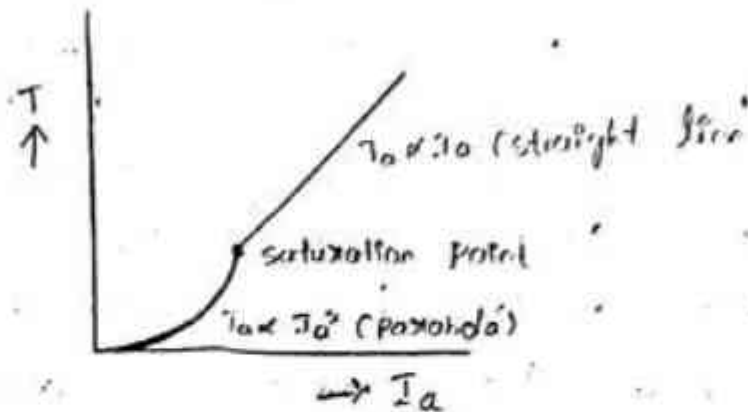
Reg. No: 11111111111111111111 Date: 22/11/2022

Subject: VEE

Class / Course: 3rd B.Tech (Bilateral) Sign: [Signature]

Series Motor

(1) Torque vs Armature current:



For dc motor the expression is

$$T_a \propto \phi I_a$$

In series motor, the flux is directly proportional to the armature current

$$\phi \propto I_a$$

~~$$T_a \propto I_a$$~~

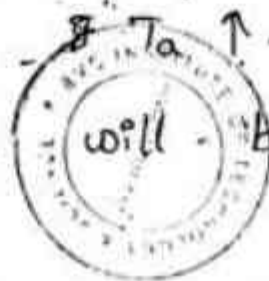
The torque is directly proportional to the square of the armature current.

$$T_a \propto I_a^2$$

If load increases, the torque also increases and the armature current square times increases.

load ↑ I_a^2 ↑↑ T_a ↑

Therefore the graph will be

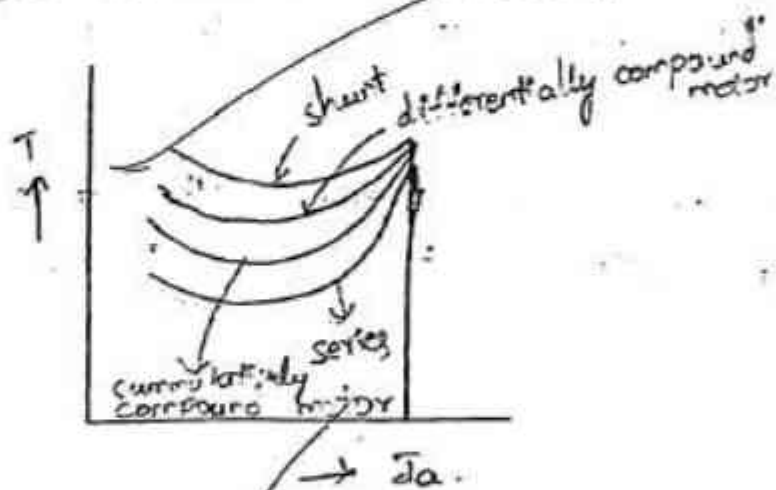


parabola when $T_a \propto I_a^2$. After it reaches saturation point then the graph is a straight line when $T_a \propto I_a$.

3. DC compound Motor:

In ~~an~~ DC compound motor is the combination of shunt and series motor. The characteristics are depends on. Cummulatively compound motor and differentially compound motor.

Torque Vs Armature Current:



In ~~the~~ Torque Vs Armature current the differentially wound compound wound motor decreases the motors.

2.(b)

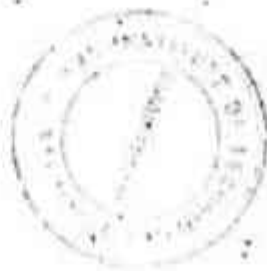
Ans

Given data.

$$V = 450 \text{ V}$$

$$R_a = 0.28 \Omega$$

$$R_{sc} = 0.32 \Omega$$



W
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Name: A. Haritha

Regd.: BI 1141A0204 Date: 22/11/20

Subject: UEE

Class / Course: 3rd sem (EEE) Invigilator Sign:

$$N_1 = 540 \text{ rpm.}$$

$$I_a = 72 \text{ A.}$$

field diverter $R = 0.872 \Omega.$

$$T_a \propto \phi I_a.$$

$$T_a = \phi I_a.$$

$$T_a \propto I_a^2.$$

$$T_1 = T_2.$$

$$\phi_1 I_{a1} = \phi_2 I_{a2}.$$

$$I_{a1} I_{a1} = I_{a2} I_{a2}$$

$$I_{a1}^2 = I_{a2}^2$$

$$I_{a1} = I_{a2} = 72 \text{ A.}$$

$$T \propto N^2$$

$$N^2 \propto I_a^2 \Rightarrow N \propto I_a$$

$$E_{b1} = V - I_a (R_a + R_{se})$$

$$= 450 - 72 (0.28 + 0.32)$$

$$= 450 - 72 (0.6)$$

$$= 406.8.$$

$$E_{b2} = V - I_a (R_a + R_{se} + R)$$

$$= 450 - 72 (0.28 + 0.32 + 0.872)$$

$$= 450 - 72 (1.472)$$

$$= 344.016$$

$$N \propto \frac{E}{\phi}$$



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$$\frac{N_1}{N_2} = \frac{E_{b1}}{E_{b2}} \times \frac{A_2}{A_1}$$

$$\frac{540}{N_2} = \frac{406.8}{344.01} \times \frac{70}{70}$$

$$\frac{540}{N_2} = 1.183$$

$$N_2 = \frac{540}{1.183}$$

$$N_2 = 456.46 \text{ rpm}$$

3. (a)

Ans:-

Advantages of electrical heating process:

1. Economical:

The electric heating equipment is cheaper, there is no required skilled persons. therefore the cost of installation is less.

2. pollution free:

there is no flue gases in electric heating so the surrounding is not pollute (or) pollution free.

3. Cleanliness:

Since dust and ash are not produced in electric heating ~~the~~ so the surroundings should maintain cleanliness.



Name: A. Haritha Roll: 81111/2021/1301 Date: 22/11/2021

Subject: UEE Class / Course: 3rd Sem / B.Tech / EEE

4. Automatic protection:

protection against over current and over heating - that can be used by fast control devices.

5. Easy to control:

The temperature can be controlled manually (or) automatically.

6. safety:

The electric heating is safe.

7. High efficiency:

In non-electric heating 40-60% heat is utilized but in electric heating 75-100% is successfully utilized. So the electric heating is high efficiency.

8. Non-conducting heating elements:

The heat can be produced by non-conducting heating elements such as wood and porcelain.

9. 9. Better working conditions.

24



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2)(b)

Ans: Direct Induction furnaces:

1. A large amount of charge is required to heat.
2. The charge is placed in the secondary winding.
3. The primary winding flux is passes the secondary winding and the charge will be heated.
4. It is based on the Induction principle.

Indirect Induction furnaces:

1. A sufficient amount of charge is required to heat.
2. The charge is placed in the inside the furnace.

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No	Regd No	PS - II		PE		PS		UEE		GDP JAVA	
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Sl. No.	Regd. No	P.S.-II		P.T.		C.S.		P.T.E.		OOP-JAVA		Total
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52	21H41A0259	13				5	11 ✓	12	9 ✓	11	12	6
53	21H41A0260	4				9	5 ✓	10	8 ✓	5	13	6

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S No	Regd. No	PS-II		PE		CS		UEE		IOTA	
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1	226M5A0215		14		9		15		15		13

Signature of the Faculty:
 Dept. Exams Incharge: *[Signature]*
 HOD: *[Signature]*
 Exams Incharge: *[Signature]*
 Principal: *[Signature]*

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BONAM VENKATA CHALAMAYYA INSTITUTE OF TECHNOLOGY & SCIENCE

Department of Mechanical Engineering

A.Y: 2023-2024

Mid-II
Max Marks: 15

Duration: 1.5Hr

Course: C NDE

Branch: M Mech

Year: IV

Semester: I

Q.No	Questions	Marks	CO	BL
1	D1) (a) Write short notes about the standard depth of penetration in Eddy Current testing. (2M) (Understanding). (b) Illustrate the principle of eddy current testing in detail? (3M) (Understanding)	5	CA13.4	L2, L3
2	Discuss the procedure of magnetic particle test in detail? (Creating)	5	CA13.6	L6
3	Explain active and passive techniques in detail. (Evaluating)	5	CA13.5	L5

Bloom's Level wise Marks Distribution



Course Outcome wise Mark Distribution



BL – Bloom's Taxonomy Levels (L1- Remembering, L2- Understanding, L3 – Applying, L4 – Analysing, L5 – Evaluating, L6 -Creating)

CO – Course Outcomes



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BL	marks
L5	5
L6	5
L2.L3	5



CO	MARKS
C413.A	5
C413.B	5
C413.S	5



B V C INSTITUTE OF TECHNOLOGY & SCIENCE:: BATLAPALEM

MID EXAM - II

IV B TECH I SEM MECH

SUB: NDE

TIME: 9.10 to 10.40 a. m DATE: 07-12-2023 MAX MARKS: 15

ANSWER ALL THE QUESTIONS

- 1) (a) Write short notes about the standard depth of penetration in Eddy Current testing.(2M) (Understanding)
(b) Illustrate the principle of eddy current testing in detail?(3M) (Understanding)
- 2) Discuss the procedure of magnetic particle test in detail? (Creating)
- 3) Explain active and passive techniques in detail. (Evaluating)



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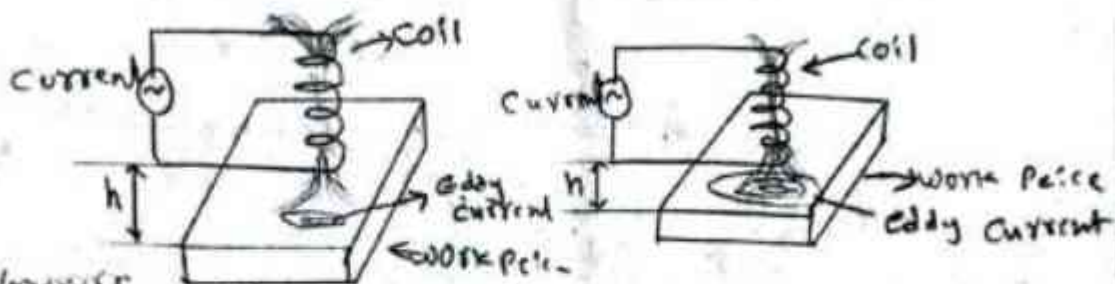
Name: BENDI GANESH Regd. No: 21H45A305 Date: 7/12/20 No. of Addit: 1

Subject: NDE

Class / Course: 4-1 SEM - B.Tech. Invigilator Sign: [Signature]

Depth penetration:-

a)



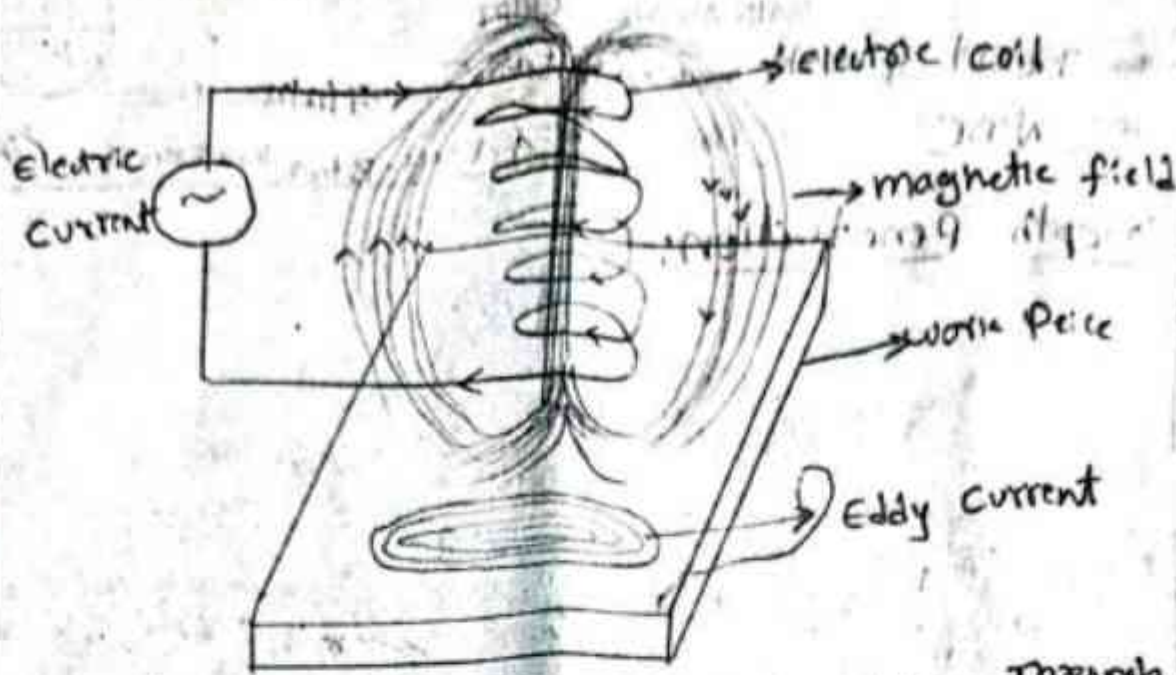
process which is used to improve the eddy current concentrations on the work piece. The height of the coil is based on work piece surface. Then the coil produce the magnetic field was highly passing through the work piece. Then the high amount of eddy current was produced. This depth penetration process is mainly depend on the distance between coil and work piece surface.

b)

Eddy current testing:-

Eddy current test is the one of the non destructive test. In these test is used to find the flaws internal cracks, slow holes, seams... etc. This eddy current test is mainly used in electric conductive



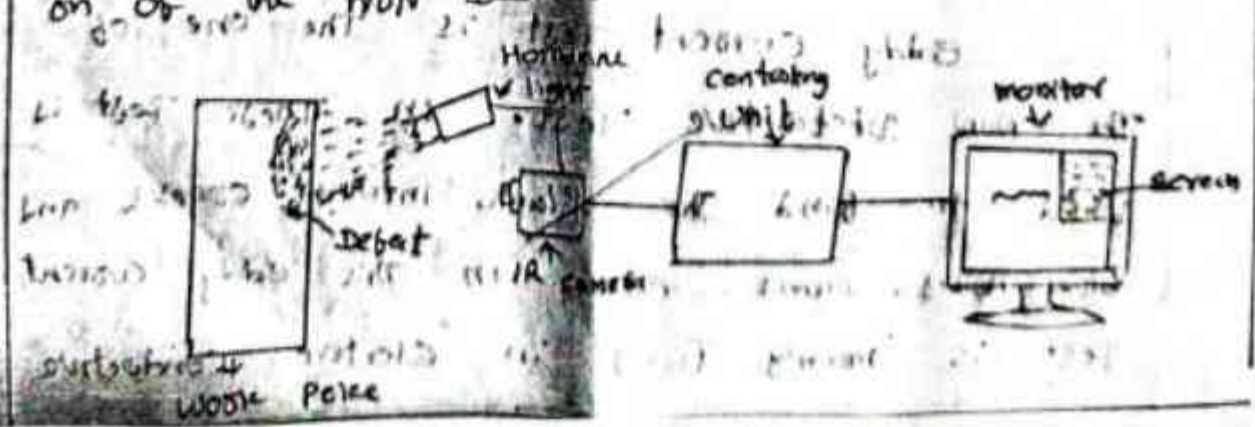


The electrical current is passing through the conductive coil. Then the electromagnetic field was developed into the coil surrounding. The magnetic field was passing through the metal. Then the eddy current was developed on work piece. The eddy current could detect the defects. It is visible on infrared screen.

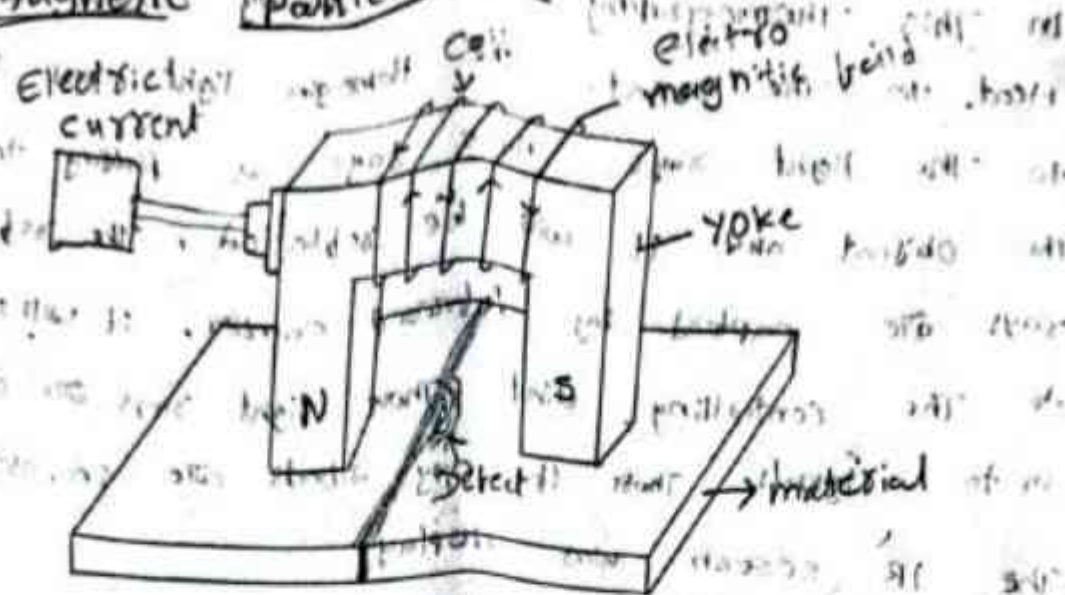
3) Active and Passive Techniques

Active Techniques

This is the Thermography technique, which is used in Thermography Testing. Thermography Test is the non-destructive test.



② Magnetic Particle Test:-



magnetic particle test is mainly perform in conductive materials only. These materials are classified in to three types. There are,

- 1] magnetic materials
- 2] Para magnetic materials
- 3] Demagnetic materials

Testing procedure:-

magnetic particle test is conducted in six processes. They are

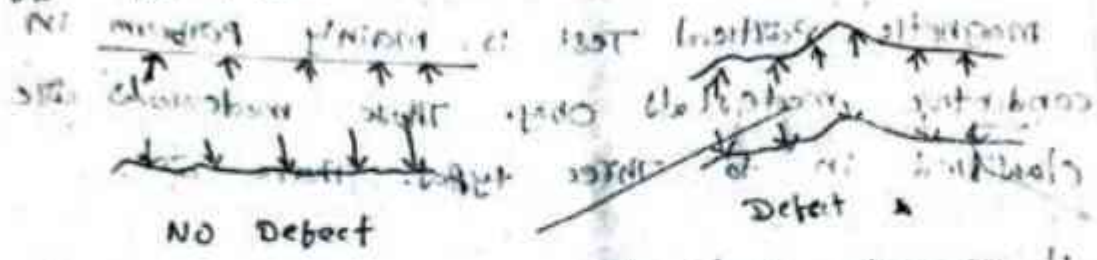
- 1] surface cleaning
- 2] Initial demagnetisation
- 3] Demagnetisation
- 4] magnetic particle Test Applications
- 5] Inspection
- 6] Result

① surface cleaning

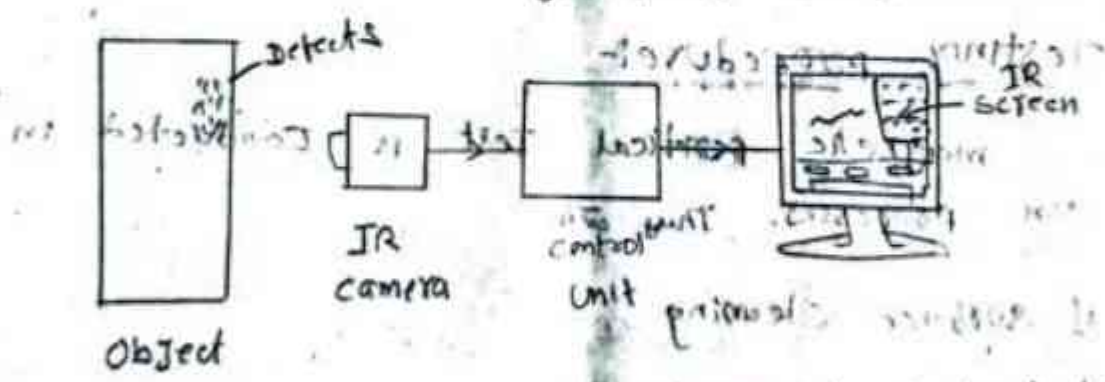
Initially The object surface was cleaning through water and Remove Rust and Dust particles

In This Thermography Test it mainly observe the heat to the object. The Homogine light was sent to the light rays. These rays are putting to the object and it will be reflected. The reflected rays are captured by infrared camera. It will sent to the controlling unit. These light rays are change in to signals. Then if any defects are in object

The IR screen was display:



Passive Technique:-



In This Technique is used in Thermography Test.

In This passive Technique is doesn't need any essential light source. The Natural light is observed on the object. The Object was Reflected in the form of heat. The Heat was captured on infrared camera. The Object having any defects like internal cracks, blow holes, seams, porosity etc. are Detects

... identified manually.

Name: B Ganesh

Regd.: 21L305

Date:

No. of Addt.:

Subject:

Class / Course:

Invigilator Sign:

1) Degreasing:-

Degreasing means the elimination of oil or grease on the material surface. If any dust or grease on the surface it will affect to the test result.

2) Initial Demagnetisation:-

The magnetic yoke etc have attraction property to the metals. So the initially current was sent into magnets. Then the magnets are losing their attraction property in gradually.

3) Demagnetisation:-

The magnetic properties are losing the magnets on sending to the current in magnets and another method is used to reduce the magnetisation. The method is induction method.

4) Applications of MPT.

- ✓ of gas pipe lines
- ✓ of Boiler pipes
- ✓ of welding joints

5) Inspection:-

The powder was spray on the surface of the work piece. If any defects are in object. Then the powder was indicates the magnetic lines. In the defects are identified manually.

M.

Regd. No	UHV2 R2041011		UMP R2041011		PPE R2041031		NDE R2041030		SE R2041010		DM R2041010	
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Sign of the Faculty.

Dept. Incharge

H O Incharge

Exams Incharge

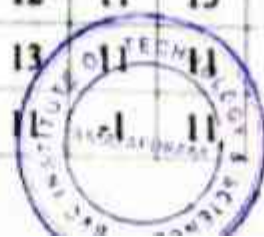
Principal



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Regd. No	UHV2 R2041011		UMP R2041011		PPE R2041011		NDE R2041012		SE R2041012		DM R2041012	
	1mid	2mid	1mid	2mid	1mid	2mid	1mid	2mid	1mid	2mid	1mid	2mid
	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15
20H41A0301	20 ²³	26	15	15	9	12	10	11	10	13	12	12
20H41A0302	25	10 ⁶	15	15	10	11	7	8	11	15	14	10
20H41A0303	25	10 ²⁰	12	14	3	12	8	10	6	12	12	9
20H41A0305	10 ¹⁰	10 ²⁰	7	12	-1	7	-1	-1	4	10	-1	0
20H41A0307	10 ¹⁰	10 ²³	-1	13	0	-1	-1	-1	-1	12	-1	10
20H41A0308	13 ²³	10	7	14	0	-1	-1	-1	6	12	-1	10
20H41A0309	20	10 ²³	14	13	0	-1	-1	-1	7	-1	-1	5
20H41A0310	24	12 ²¹	15	14	8	12	7	6	7	11	12	10
20H41A0311	20	12 ¹¹	15	14	0	9	-1	6	9	11	-1	11
20H41A0312	26	10 ²²	12	14	2	12	-1	7	7	11	-1	9
20H41A0313	28	10 ²²	14	14	0	7	7	5	8	10	9	11
21H45A0301	24	28	15	15	4	15	8	12	7	14	11	13
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21H45A0313	10 ¹⁰	24	15	15	14	12	12	15	11	14	10	12
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21H45A0318	20 ²⁴	26	15	15	5	11	11	11	9	12	11	13

7.6



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Regd. No	UHV2 R2041011		UMP R204101K		PPE R204103H		NDE R204103Q		SE R204101Q		DM R204101V	
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	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15
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21H45A0338	28	14	15	13	13	9	14	8	13	11	13	
21H45A0339	22	24	15	15	5	14	10	14	8	11	11	

Sign of the Faculty: *[Handwritten signatures]*

Dept. Exams Incharge *[Handwritten signature]*

Exams Incharge *[Handwritten signature]*

Principal *[Handwritten signature]*



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BONAM VENKATA CHALAMAYYA INSTITUTE OF TECHNOLOGY & SCIENCE

Department of Electronics and Communication Engineering

MID-1

Max Marks: 15

Duration: 1 1/2Hr

A.Y: 2022-23

Course: VLSI

Branch: ECE

Year: III

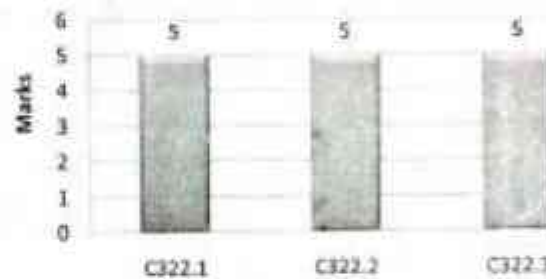
Semester: I

Q.No	Questions	Marks	CO	BL
1	1. Draw the circuit for NMOS inverter and explain its operation and characteristics. Determine pull-up to pull-down ratio of an NMOS inverter when driven another NMOS inverter	5M	C322.1	L3
2	Calculate Delays for The Following Inverters a) NMOS inverter pair: -----2M b) CMOS inverter pair: -----3M	5M	C322.2	L3
3	Draw the circuit diagram of single stage amplifier and calculate voltage gain with a) Resistive load -----2M b) Diode connected load [without body effect and [with body effect] ----3M	5M	C322.3	L3

Bloom's Level wise Marks Distribution



Course Outcome wise Mark Distribution



Course Outcome wise percentage coverage



RL - Bloom's Taxonomy Levels (L1- Remembering, L2- Understanding, L3 - Applying, L4 - Analysing, L5 - Evaluating, L6 - Creating)

CO - Course Outcomes

Faculty Signature



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BONAM VENKATA CHALAMAYYA INSTITUTE OF TECHNOLOGY & SCIENCE
DEPARTMENT OF ELECTRONICS & COMMUNICATION ENGINEERING

Course Name: VLSI DESIGN

Year / Sem: IIIB.Tech/II Sem

AY: 2023-2024

Faculty Name: P.Girish

Course Code: C322

SCHEME OF EVALUATION WITH CO AND BT MAPPING

Q.No	Questions	Marks	CO	BT
1	Draw the circuit for NMOS inverter and explain its operation and characteristics. Determine pull-up to pull-down ratio of an NMOS inverter when driven another NMOS inverter.	5M	C322.1	Apply
2	. Calculate Delays for The Following Inverters a) NMOS inverter pair. -----2M b) CMOS inverter pair. -----3M	5M	C322.2	Understand
3	Draw the circuit diagram of single stage amplifier and calculate voltage gain with a) Resistive load -----2M b) Diode connected load [without body effect and [with body effect] -- --3M	5M	C322.3	Analyze

1. Draw the circuit for NMOS inverter and explain its operation and characteristics. Determine pull-up to pull-down ratio of an NMOS inverter when driven another NMOS inverter.

1. Diagram:1M
2. Explanation:2M
3. Derivation:.....2M

2. Calculate Delays for The Following Inverters

- a) NMOS inverter pair, -----2M
- b) CMOS inverter pair. -----3M

3. Draw the circuit diagram of single stage amplifier and calculate voltage gain with

- a) Resistive load -----2M
- b) Diode connected load [without body effect and [with body effect] ----3M

Faculty Signature




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Name: G. L. Anusri
 Subject: VLSI

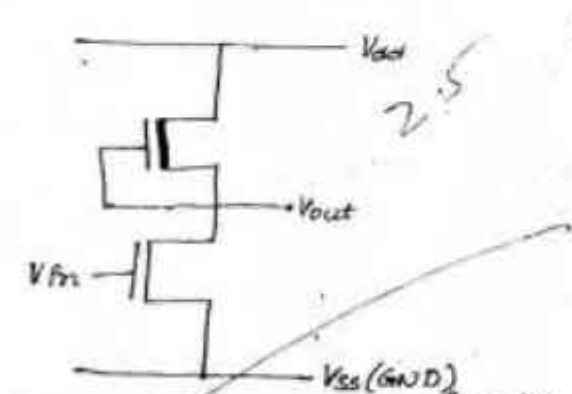
Regd.: 21H41A0417
 Class/Course: ECE-A(3-2)

Date: 27-02-24 No. of Adds.:
 Invigilator Sign: ↓

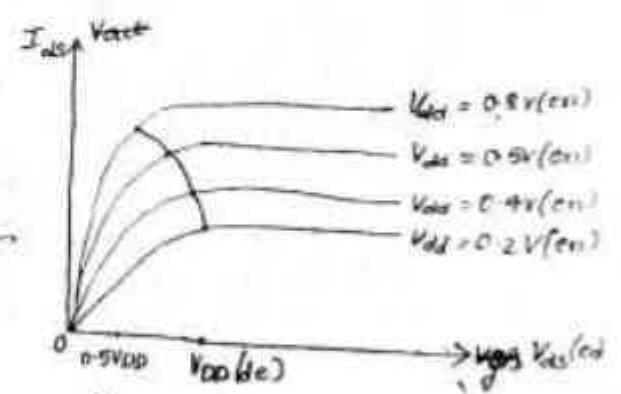
1.1c - NMOS Inverter

1-5, 20-2, 25-2, 30-5
 Verified by G. L. Anusri

- * A basic requirement for producing complex range of logic circuits is an inverter. These are needed for restoring the logic levels, for NAND and NOR gates, sequential and memory logics for various forms.
- * For a basic NMOS inverter, we require a transistor which is given from source to ground and load resistor is given from drain to supply V_{DD} . The output is taken at drain and inputs are in between gate and ground.
- * Resistors are not convenient in the silicon substrate due to it occupies more space (large area). For that we require a another type of load resistance. The convenient way to solve the problem is depletion mode transistor is used as load.



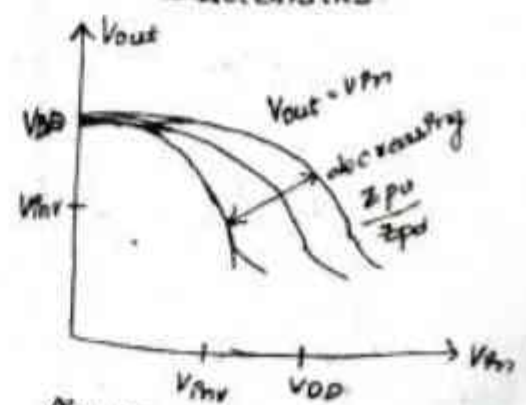
figs - circuit of NMOS inverter



$V_{ds}(en) = V_{DD} - V_{ds}(dep) = V_{in}$
 $V_{DD}(dep) = V_{out}$

figs - Derivation for NMOS transfer characteristics

- * Current I_{ds} for transistor inverter is equal.
- * By shown in the figure, enhancement mode device is known as pull-up and depletion mode device is known as pull-down inverter.



figs - Transfer function

Determining the pull-up to pull-down ratio of an NMOS Inverter when driven another NMOS Inverters.

* To determine the pull-up to pull-down ratio of an NMOS Inverter when driven another NMOS Inverter.



$$\text{Current } I_{ds} = k \frac{w}{L} \frac{(V_{gs} - V_t)^2}{2}$$

For enhancement mode transistor

$$I_{ds} = k \frac{w_{pd}}{L_{pd}} \frac{(V_{gs} - V_t)^2}{2}$$

where $V_{gs} = V_{in} = V_{inv}$

$$I_{ds} = k \frac{w_{pd}}{L_{pd}} \frac{(V_{inv} - V_t)^2}{2} \rightarrow (1)$$

For depletion mode transistor

$$I_{ds} = k \frac{w_{pu}}{L_{pu}} \frac{(V_{gs} - V_t)^2}{2}$$

where $V_{gs} = 0$, $V_t = V_{td}$

$$I_{ds} = k \frac{w_{pu}}{L_{pu}} \frac{(-V_{td})^2}{2} \rightarrow (2)$$

From (1) & (2)

$$\frac{k w_{pd}}{L_{pd}} \frac{(V_{inv} - V_t)^2}{2} = \frac{k w_{pu}}{L_{pu}} \frac{(-V_{td})^2}{2}$$

$$\frac{1}{z_{pd}} (V_{inv} - V_t)^2 = \frac{1}{z_{pu}} (V_{td})^2$$

$$\left[\because \frac{w}{L} = z \right]$$

$$\boxed{\frac{z_{pu}}{z_{pd}} = \frac{V_{td}^2}{(V_{inv} - V_t)^2}}$$

Let us consider

$$V_{td} = -0.6 V_{dd}$$

$$V_{inv} = 0.2 V_{dd}$$

$$V_t = 0.5 V_{dd}$$

$$\frac{z_{pu}}{z_{pd}} = \frac{(-0.6)^2}{(0.2 - 0.5)^2}$$

$$\frac{z_{pu}}{z_{pd}} = \frac{4}{1}$$

$$\boxed{z_{pu} : z_{pd} = 4 : 1}$$

∴ So the NMOS Inverter is driven by another NMOS Inverter.

2.10 a) NMOS Inverter pair delay

The NMOS Inverter is having a output of inverter 1 is connected to input of inverter 2. The NMOS Inverter pair delay is having a 4:1 ratio. The Z_{pd} is having longest number as 4 when the Z_{pu} is having less transistor.

$$R_{pd} = 4R_s = 40k\Omega$$

where, as for R_{pu} is having $1R_s = 10k\Omega$.

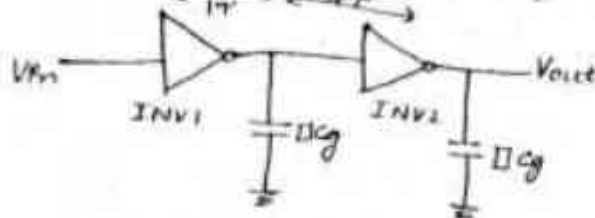
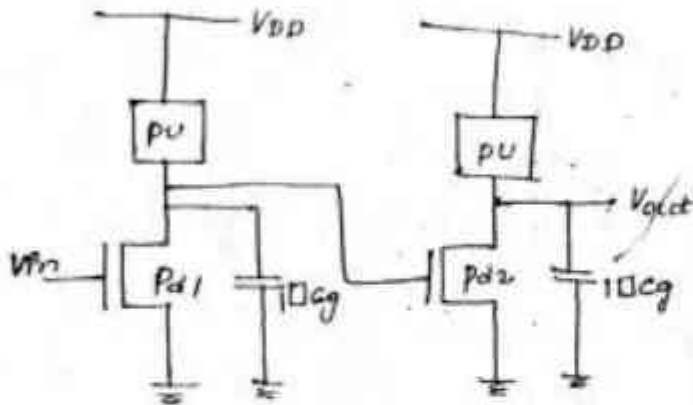


fig- NMOS Inverter pair delay.



* At $V_{in} = 0$ then, pd_1 is in off state then due to pull-up inverter capacitance (c_g) is charging.

* At $V_{in} = 1$ then pd_1 is in ON state, due to pd_1 capacitance (c_g) is discharging.

$$\tau_1 = Z_{pu} 10c_g$$

$$\tau_2 = Z_{pd} 10c_g$$

$$\tau_{tot} = \tau_1 + \tau_2 = Z_{pd} 10c_g + Z_{pu} 10c_g$$

$$= Z_{pd} 10c_g \left[1 + \frac{Z_{pu}}{Z_{pd}} \right]$$

where $\frac{Z_{pu}}{Z_{pd}} = \frac{4}{1}$

$$= Z_{pd} 10c_g [1 + 4]$$

$$= Z_{pd} 10c_g [5] \quad (\because \tau = Z_{pd} 10c_g)$$

$\tau_{tot} = 5\tau$ \therefore For NMOS Inverter pair delay $\tau_{tot} = 5\tau$

(b) CMOS Inverter pair -

* In CMOS Inverter pair, the NMOS Inverter pair delay condition is not necessary they both are completely different.

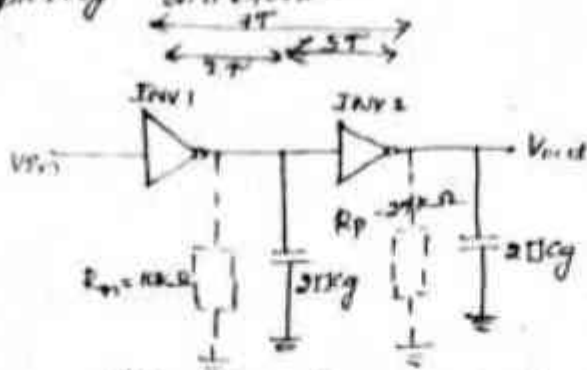
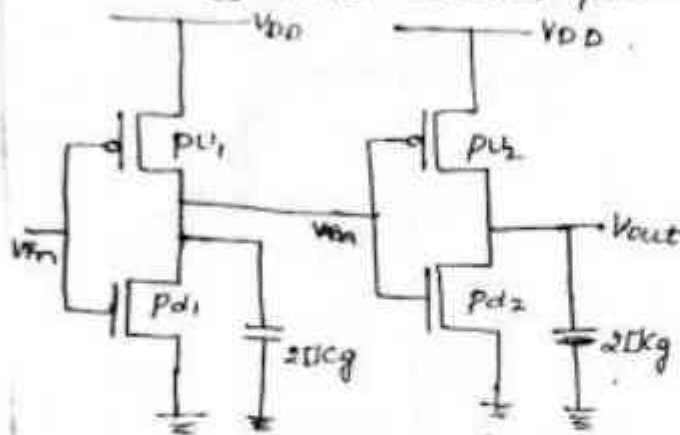


fig - CMOS Inverter pair delay



$$T_1 = Z_{pd} \cdot 20 \text{pF}$$

$$T_2 = Z_{pu} \cdot 20 \text{pF}$$

$$Z_{pd} = R_n = 10 \text{k}\Omega$$

$$Z_{pu} = R_p = 25 \text{k}\Omega$$

$$\frac{Z_{pd}}{Z_{pu}} = \frac{25 \text{k}\Omega}{10 \text{k}\Omega} = 2.5 \text{k}\Omega$$

$$\frac{Z_{pd}}{Z_{pu}} = \frac{R_n}{R_p} = 2.5 \text{k}\Omega \Rightarrow R_p = 2.5 \text{k}\Omega R_n$$

$$T_{tot} = T_1 + T_2 = Z_{pd} \cdot 20 \text{pF} + Z_{pu} \cdot 20 \text{pF}$$

$$= Z_{pd} \cdot 20 \text{pF} +$$

$$= R_n \cdot 20 \text{pF} + R_p \cdot 20 \text{pF}$$

$$= R_n \cdot 20 \text{pF} + 2.5 \cdot R_n \cdot 20 \text{pF}$$

$$= R_n \cdot 20 \text{pF} [1 + 2.5 \times 2]$$

$$= R_n \cdot 20 \text{pF} [7]$$

$$T_{tot} = 7T$$

$$(\because T = R_n \cdot 20 \text{pF})$$

\(\therefore\) For CMOS Inverter pair delay $T_{tot} = 7T$.

Name: G. L. Anusri

Class / Course: B.TECH / ECE

Date: 27.12.24

Regd No: VLSE

Subject: ECE-A (3-2)

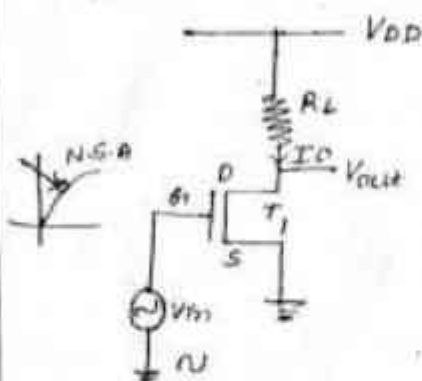
Instructor Sign: ✓

3. Common Source Stages -

(a) common source stage with resistive load -

* The common source stage is finding using a resistive load.

* The circuit diagram of common source stage is shown in the below figure.



* When $V_{in} = 0$ then T_1 will be in OFF stage the output $V_{out} = V_{DD}$.

* When $V_{in} > V_{th}$ then T_1 will be in non-saturation condition. Then the output $V_{out} = V_{DD} - I_D R_D$.

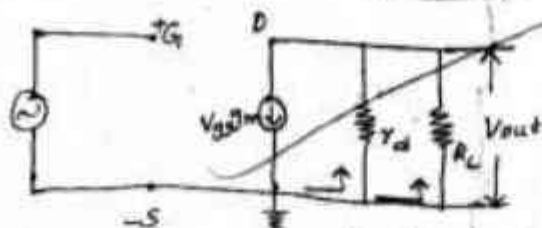
$$I_D = k \frac{W}{L} (V_{GS} - V_{th}) V_{DS} - \frac{V_{DS}^2}{2}$$

$$V_{out} = V_{DD} - \left[k \frac{W}{L} (V_{GS} - V_{th}) V_{DS} - \frac{V_{DS}^2}{2} \right] R_D$$

* When V_{in} still increases, then T_1 will be in saturation condition.

then the output

$$V_{out} = V_{DD} - \left[k \frac{W}{L} (V_{GS} - V_{th})^2 \right] R_D$$



To find A_v , Z_i , Z_o when take $Z_{in} = \infty$.

$$\text{Gain}(A_v) = \frac{V_{out}}{V_{in}}$$

$$V_{out} = -g_m V_{gs} (R_D || R_L)$$

$$V_{gs} = v_{in}$$

$$V_{out} = -g_m v_{in} (r_d \parallel R_L)$$

$$\frac{V_{out}}{v_{in}} = -g_m (r_d \parallel R_L)$$

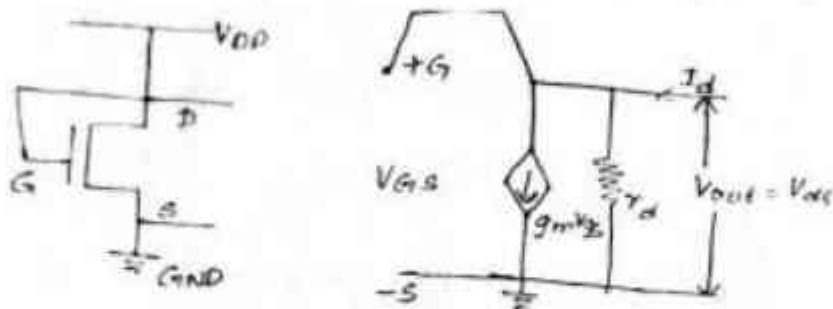
$$A_v = -g_m (r_d \parallel R_L)$$

$$Z_i = \infty$$

$$Z_o = r_d \parallel R_L$$

b) Diode connected loads-

Common source stage with diode connected load, resistive load and diode fabrication process.



$$I_d = g_m v_{gs} + \frac{V_{ds}}{r_d}$$

shortage (n-D Terminal)

$$V_{ds} = v_{gs}$$

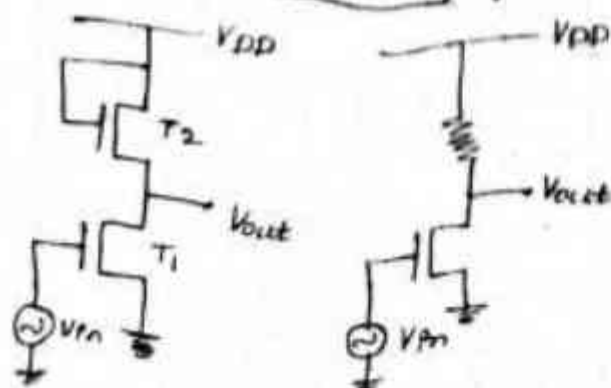
$$I_d = g_m v_{ds} + \frac{V_{ds}}{r_d}$$

$$I_d = v_{ds} \left[g_m + \frac{1}{r_d} \right]$$

$$\frac{I_d}{v_{ds}} = g_m + \frac{1}{r_d} \quad (\because V_{ds} = v_{gs})$$

$$\frac{I_d}{v_{gs}} = g_m + \frac{1}{r_d}$$

$$R_L = \frac{1}{g_m + \frac{1}{r_d}}$$





Name: G. L. Anwar

Class / Course: ECE-A (3-2)

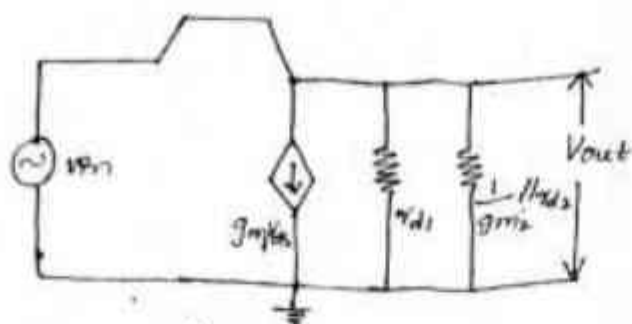
Date: 27-08-24

Regd No: 417

Subject: VLSI

Instructor Sign: ✓

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$$V_{out} = -g_m v_{gs} \left(r_{d1} \parallel \frac{1}{g_{m2}} \parallel r_{d2} \right)$$

$$V_g = v_{in}$$

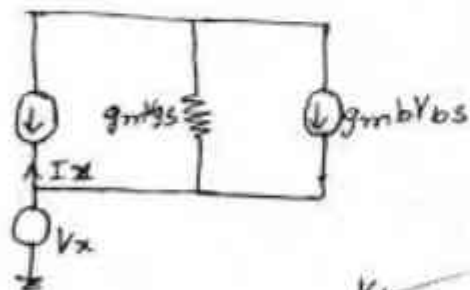
$$V_{out} = -g_m v_{in} \left(r_{d1} \parallel \frac{1}{g_{m2}} \parallel r_{d2} \right)$$

$$\frac{V_{out}}{v_{in}} = -g_m \left(r_{d1} \parallel \frac{1}{g_{m2}} \parallel r_{d2} \right)$$

$$A_v = -g_m \left(r_{d1} \parallel \frac{1}{g_{m2}} \parallel r_{d2} \right)$$

$$Z_i = \infty \Rightarrow Z_o = r_{d1} \parallel \frac{1}{g_{m2}} \parallel r_{d2}$$

Common source stage with diode connected load using body effect



$$I_x = g_m v_{gs} + \frac{V_{ds}}{r_d} + g_{mb} V_{bs}$$

$$V_{gs} = V_{ds} = V_{bs} = V_x$$

$$I_x = g_m V_x + \frac{V_x}{r_d} + g_{mb} V_x$$

$$I_x = V_x \left[g_m + \frac{1}{r_d} + g_{mb} \right]$$

$$\frac{V_x}{I_x} = \frac{1}{g_m + \frac{1}{r_d} + g_{mb}}$$

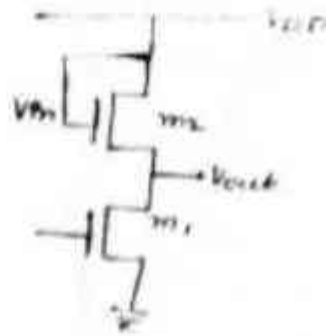
$$R_o = \frac{1}{g_m + g_{mb} + r_d^{-1}}$$

Voltage gain

$$A_v = -g_m R_D$$

$$= -g_{m1} \left[\frac{1}{g_{m1} + g_{m2}} \right] V_{in}$$

$$A_v = \frac{-g_{m1}}{g_{m2}} \left[1 + \frac{1}{\eta} \right]$$



Small signal

$$A_v = \frac{-\sqrt{2} \mu_n C_{ox} \left(\frac{W}{L} \right)_1 I_{D1}}{-\sqrt{2} \mu_n C_{ox} \left(\frac{W}{L} \right)_2 I_{D2}} \times I_{D2} \left(\frac{1}{1 + \eta} \right)$$

$I_{D2} \Rightarrow I_{D1} = I_{D2}$

$$A_v = \sqrt{\left(\frac{W}{L} \right)_1} / \sqrt{\left(\frac{W}{L} \right)_2} \left(\frac{1}{1 + \eta} \right)$$



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S. No.	Regd. No.	MP MC R2012041		VLSI D R2012042		DSP R2012043		MWE R2012045		C N R2012018	
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	21H41A0405	5	9 ¹²	4	12	15	15	8	11	6	8
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	21H41A0413	4	13	15	-1	13	15	11	-1	13	7
	21H41A0414	13	11	13	12	15	15	12	15	13	14
	21H41A0415	4	-1	9	10	13	12	10	-1	6	9
	21H41A0416	9	12	8	6	15	10	8	10	12	11
	21H41A0417	10	12	15	12	15	13	14	15	15	13
	21H41A0418	5	10	9	7	14	12	8	-1 ¹⁰	15	9
	21H41A0419	9	13	14	10	15	14	11	11	15	14
	21H41A0420	1	9	12	-1	13	15 ¹⁰	10	-1	7	12
	21H41A0421	7	12	15	11	15	15	12	-1	15	14
	21H41A0422	11	12	14	15	15	15	-1	15	14	14
	21H41A0424	10 ²	-1	12 ¹⁰	-1	13	14	-1	-1 ¹⁰	5	8
	21H41A0425	12	12	10	14	15	15	10	13	13	14
	21H41A0426	14	11	12	12	15	15	8	-1 ¹⁰	14	10
	21H41A0427	5	12	10	11	12	14	10	11	5	10
	21H41A0428	8	11	5	13	15	13	11	14	5	9
	21H41A0429	10	11	8	13	15	15	10	14	11	11

(66)



BVC Institute of Technology & Science
 BATLAPALEM - 533 211
 (Vta) Amalapuram, DR.B.R.A.K.Dist.

Sl. No.	Regd. No	MP MC R2012041		VLSI D R2012042		DSP R2012043		MWE R201204A		CN R201204K	
		Final	Final	Final	Final	Final	Final	Final	Final	Final	Final
		max 15	max 15	max 15	max 15	max 15	max 15	max 15	max 15	max 15	max 15
21H41A04B9	9	12	15	14	14	15	13	15	13	11	
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21H41A04C2	2	6	13	3	12	13	10	12	-1	11	
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21H41A04C6	9	12	14	14	15	15	12	12	8	11	
21H41A04C8	7	11	10	13	15	15	10	14	2	13	
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22H45A0408	12	12	15	14	15	15	11	11	12	12	
22H45A0409	13	10	14	12	15	15	10	12	14	13	
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22H45A0411	12	13	15	13	15	15	13	12	14	13	
22H45A0412	9	12	14	13	14	15	9	10	13	10	

Signature of the Faculty: 

Dept. Exams Incharge

HOD

Exams Incharge

Principal



PRINCIPAL
BVC Institute of Technology & Science
BATLAPALEM, AMALAPURAM - 533 224

BVC Institute of Technology & Science
BATLAPALEM - 533 224
(Viv) Amalapuram, DR.B.R.A.K. Dist.



B V C INSTITUTE OF TECHNOLOGY & SCIENCE :: BATLAPALEM

MID EXAM - I

III B TECH I SEM - CSE

SUB: DWDM

TIME: 9.30 to 11.00 am

DATE 21.09.2023

MAX MARKS: 15

ANSWER ALL THE QUESTIONS.

1. Differentiate Operational database systems and data warehousing. **(C313.1-Analyzing)**
2. Given the following data (in increasing order) for the attribute age: **(C313.2-Applying)**
13, 15, 16, 16, 19, 20, 20, 21, 22, 22, 25, 25, 25, 25, 30, 33, 33, 35, 35, 35, 35, 36, 40, 45, 46, 52, 70.
 - (i) Use min-max normalization to transform the value 35 for age onto the range [0.0,1.0].
 - (ii) Use z-score normalization to transform the value 35 for age, where the standard deviation of age is 12.94 years.
 - (iii) Use normalization by decimal scaling to transform the value 35 for age.
3. What is attribute selection measure. Briefly describe the attribute selection measures for decision tree induction. **(C313.3-Applying)**

BONAM VENKATA CHALAMAYYA INSTITUTE OF TECHNOLOGY & SCIENCE
DEPARTMENT OF COMPUTER SCIENCE AND ENGINEERING

Scheme of Evaluation With CO and BT Mapping

Course : DATA WAREHOUSING AND DATA MINING(C313)
Class: III B.Tech I Sem Mid Examination-1
AY: 2023-24

SCHEME OF EVALUATION WITH CO AND BT MAPPING

SNO	QUESTION	CO	BT
1.	Differentiate Operational database systems and data warehousing.	C313.1	Apply
2	Given the following data (in increasing order) for the attribute age: 13, 15, 16, 16, 19, 20, 20, 21, 22, 22, 25, 25, 25, 25, 30, 33, 33, 35, 35, 35, 35, 36, 40, 45, 46, 52, 70. (i) Use min-max normalization to transform the value 35 for age onto the range [0.0,1.0]. (ii) Use z-score normalization to transform the value 35 for age, where the standard deviation of age is 12.94 years. (iii) Use normalization by decimal scaling to transform the value 35 for age.	C313.2	Analyze
3	What is attribute selection measure. Briefly describe the attribute selection measures for decision tree induction.	C313.3	Apply

1. Differentiate Operational database systems and data warehousing.

Ans: Define OLAP and OLTP(1M)

Any 8 differences between OLAP and OLTP (4M)

2. Given the following data (in increasing order) for the attribute age:

13, 15, 16, 16, 19, 20, 20, 21, 22, 22, 25, 25, 25, 25, 30, 33, 33, 35, 35, 35, 35, 36, 40, 45, 46, 52, 70.

(i) Use min-max normalization to transform the value 35 for age onto the range [0.0,1.0].

(ii) Use z-score normalization to transform the value 35 for age, where the standard

deviation of age is 12.94 years.

(iii) Use normalization by decimal scaling to transform the value 35 for age.

Ans:

- i) Min-Max Normalization with formula-2M
 - ii) Z-Score Normalization with formula-2M
 - iii) Normalization by Decimal scaling-1M
3. What is attribute selection measure. Briefly describe the attribute selection measures for decision tree induction.

Ans: Define Attribute selection measure-1M

Information Gain-2M

Gain Ration-1M

Gini Index-1M

D. Suleman
Faculty

BONAM VENKATA CHALAMAYYA INSTITUTE OF TECHNOLOGY & SCIENCE
Department of Computer Science & Engineering

A.Y: 2023-24

Course: Data Warehousing and Data Mining(MID - 1)

Max Marks: 15

Branch: CSE

Year: III

Semester: I

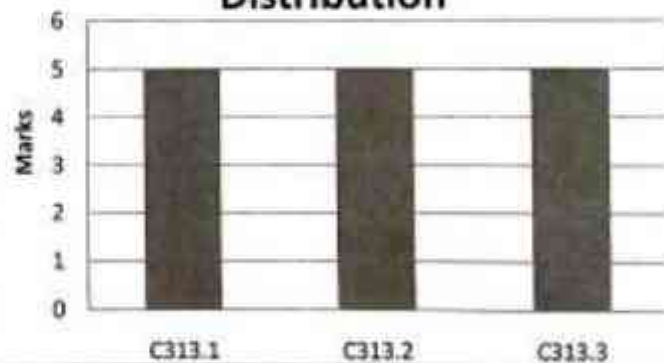
Duration: 1 Hr 30 Mins

Q.No	Questions	Marks	CO	BL
1	Differentiate Operational database systems and data warehousing.	5	C313.1	L3
2	Given the following data (in increasing order) for the attribute age: 13, 15, 16, 16, 19, 20, 20, 21, 22, 22, 25, 25, 25, 25, 30, 33, 33, 35, 35, 35, 35, 36, 40, 45, 46, 52, 70. (i) Use min-max normalization to transform the value 35 for age onto the range [0.0,1.0]. (ii) Use z-score normalization to transform the value 35 for age, where the standard deviation of age is 12.94 years. (iii) Use normalization by decimal scaling to transform the value 35 for age.	5	C313.2	L4
3	What is attribute selection measure. Briefly describe the attribute selection measures for decision tree induction.	5	C313.3	L3

**Bloom's Level wise Marks
Distribution**



**Course Outcome wise Mark
Distribution**



BL – Bloom's Taxonomy Levels (L1- Remembering, L2- Understanding, L3 – Applying, L4 – Analysing, L5 – Evaluating, L6 - Creating)

CO – Course Outcomes

C313.1: Outline the Importance of Data Warehousing and Features of Data Mining(Understand)

C313.2: Demonstrate data Preprocessing Techniques and process raw data to make it suitable for Data mining.(Apply)

C313.3: Apply decision tree classification techniques for data analysis.(Apply)

V. Venkatesh
FACULTY

4+5+5
Verified by
14
15
A. K. Gopal

Name: A. Lalitha Gayathri Regd. : 21141A0505 Date: 21/9/23 No. of Atts: 1

Subject: DMDW Class / Course: III B-Tech. ISCM Invigilator Sign:

Q1A) Differences between operational database systems and data warehousing:-

Feature	OLTP	OLAP
Full form	Online Transactional Processing	Online analytical processing
Characterization	processed in a transactional way	processed in a analytical way.
Orientation	Transaction	Analysis of information
User	clerk, database design, software professions	Knowledgeable persons in analytical processing
Function	E-R based function will be done.	Subject oriented function will be done (star/snowflake)
DB design	It will be designed in application oriented	It will be designed, in information-oriented.
Data	It will be in short and simple forms	It has complex queries.
Summarization	Predictive, Summarized	Summarized, consolidated
View	Having in simple databases	Summarized and multidimensional user views.
Unit of work	current, guaranteed	historical work

Access	Data in	Information out
Focus	How data is transferred in transactional processing	How data that inform out using analytical processing
Operations	It performs index and high operations	It performs simple queries only.
User	Read/write will perform	Read only mostly perform.
Number of records accessed	tons	millions
Number of users	thousands	hundreds.
DB size	100 MB to GB	100 GB to TB
Performance	Having high performance due to the simple and short database	Having low performance due to the complex queries
Priority	High performance, high flexibility	High informational, end user autonomy
Metric	Transaction throughput, and guaranteed transaction processing	Information throughput and response time
Information storing	In this information will be stored as database relational tables	In this information will be stored as complex queries.



Q) Given,

13, 15, 16, 16, 19, 20, 20, 21, 22, 22, 25, 25, 25, 25, 30,
33, 33, 35, 35, 35, 35, 36, 40, 45, 46, 52, 70.

(i) min-max normalization to transform the value 35 for age onto the range $[0.0, 1.0]$:-

$$V_i = 35$$

$$\text{min}_A = 13$$

$$\text{max}_A = 70$$

$$\text{new max}_A = 1.0$$

$$\text{new min}_A = 0.0$$

$$V_i' = \frac{V_i - \text{min}_A}{\text{max}_A - \text{min}_A} [\text{new max}_A - \text{new min}_A] + \text{new min}_A$$

$$= \frac{35 - 13}{70 - 13} [1.0 - 0.0] + 0.0$$

$$= \frac{22}{57} [1]$$

$$= 0.385$$

(ii) Use Z-score normalization to transform the value 35 for age, when the standard deviation of age is 12.94 years.

$$V_i = 35$$

$$\sigma_A = 12.94$$

$$V_i' = \frac{V_i - \bar{A}}{\sigma_A}$$

$$\bar{A} = \frac{13 + 15 + 16 + 16 + 19 + 20 + 20 + 21 + 22 + 22 + 25 + 25 + 25 + 25 + 30 + 30 + 33 + 33 + 35 + 35 + 35 + 35 + 36 + 40 + 45 + 46 + 52 + 70}{27}$$

$$= \frac{809}{27} = 29.96$$

$$= 29.996$$

$$\sqrt{20}$$

$$V_i' = \frac{V_i - \bar{A}}{s} = \frac{35 - 29.96}{12.94} = 0.3814$$

$$= \frac{35 - 30}{12.94} = \frac{5}{12.94} = 0.386$$

$$V_i' = 0.386$$

$$\therefore V_i' = 0.389$$

$$\therefore V_i' = 0.548 \quad V_i' = 0.456$$

(ii) Normalization by decimal scaling to transform the value 35 for age.

$$V_i = 35$$

$j = 2$ (Here $V_i = 35$ 0 decimals so, $j = 2$).

$$V_i' = \frac{V_i}{10^j}$$

$$= \frac{35}{10^2}$$

$$= \frac{35}{100}$$

$$= 0.35$$

(3A) Attribute Selection measure:-

* Attribute selection measure is used to calculate the attribute test conditions of decision tree based on the training set.

* Attribute selection measure contains three kinds of measures:-
(1) Information Gain
(2) Gain ratio
(3) Gini Index

Name : A. Lalitha Gayatri
Subject : DMDW

Regd. : 24/11/2023
Class / Course :

Date : 21/9/23 No. of Addit : 1
Invigilator Sign :

Attribute selection measures for decision tree induction:-

- * Decision tree induction means the process of learning decision tree based from the training set.
- * Training set contains attributes and class labels.
- * It has 3 selection measures:-
 - (1) Information Gain
 - (2) Gain ratio
 - (3) Gini Index.

(1) Information Gain:-

- * The ID3 algorithm makes use of the measure called information Gain.
- * As it attribute selection measure decision tree get used to calculate information gain
- * The extent of information gain is used to specify the measure of selection and tuples 'D' will be estimated as:-

$$Info(D) = - \sum_{i=1}^m p_i \log_2 p_i$$

Where, $p_i = |C_i, D| / |D|$

m is the no. of distinct values

p_i is the non-zero probability that has arbitrary tuple which belongs to class C_i .

* Information gain is also called the entropy of 'D'.
* In some cases we need to partition the attribute A in the tuple D having n distinct values is represented as: (A_1, A_2, \dots, A_n)

* The Information Gain of that particular attribute A of tuple 'D' we can be estimated as:-

$$Info_A(D) = \sum_{j=1}^n \frac{|D_j|}{|D|} \times Info(D_j)$$


* The Information Gain will be defined as difference between Original Information of requirements and after partition on A of the Information requirements:-

$$\therefore Gain(A) = Info(D) - Info_A(D)$$

(ii) Gain ratio:-

- * Gain ratio is the one of the attribute selection measure for decision tree induction.
- * Gain ratio is the extension of the information gain.
- * Gain ratio will overcome the problem of the information gain which is if the text contains many many text it will be calculated.
- * To solve this, it apply some kind of the normalization to overcome that problem.

Name: A. Lalitha Gayatri Regd. : 2111V10005 Date: No. of Addit: 2

Subject: DMNW Class / Course: Invigilator Sign: 

* We use the splitting method to normalize the information gain in gain ratio.

* It will be estimated as:-

$$\text{SplitInfo}_A(D) = \sum_{j=1}^n \frac{|D_j|}{|D|} \times \log_2 \frac{|D_j|}{|D|}$$

* Therefore gain ratio will be defined as:-

$$\text{GainRatio}(D) = \frac{\text{Gain}(A)}{\text{SplitInfo}_A(D)}$$

(ii) Gini Index:-

* Gini index is the one of the attribute selection measures for decision tree induction.

* Gini index is used to calculate the impurity of D which is represented as:-

$$\text{Gini}(D) = 1 - \sum_{i=1}^n p_i^2$$

where,

p_i is the probability of tuples

n is the no of distinct values

$$p_i = \frac{|c_i, D|}{|D|} \quad \text{p.t.o.}$$

D = tuples

* Gini index is used to do binary splitting because it supports only binary splitting

Example:-

{low, medium, high}

Subsets

(i) {low, medium} and {high}

(ii) {low, high} and {medium}

(iii) {medium, high} and {low}

* Gini index is used to support binary splitting and best attribute is selected as attribute measure.

(5) * In Gini index the attribute are divided into partitions if the attribute measure is 0. zero (0) then the D is divided into partitions such as D_1, D_2, \dots, D_n

$$Gini_A(D) = \frac{|D_1|}{|D|} Gini(D_1) + \frac{|D_2|}{|D|} Gini(D_2) + \dots$$

Regd. No	CN R2031051		DAA R2031052		DWDM R2031053		FMM R2031041 ✓		SPM R203105B	
	1mid	2mid	1mid	2mid	1mid	2mid	1mid	2mid	1mid	2mid
	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15	mm 15
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21H41A0502	10	12	8	10	12	10	10	13	15	14
21H41A0503	13	14	14	15	14	14	15	15	15	15
21H41A0504	13	13	11	15	14	14	15	14	15	15
21H41A0505	14	15	12	15	14	14	15	15	15	15
21H41A0506	14	13	14	14	14	14	15	15	15	15
21H41A0507	12	13	10	11	10	12	12	14	15	15
21H41A0508	11	13	13	13	11	14	13	15	15	15
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21H41A0510	7	12	10	12	9	12	12	13	15	15
21H41A0511	8	13	8	12	11	14	11	11	15	14
21H41A0512	3	8	6	9	4	8	11	11	13	15
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21H41A0517	13	13	12	14	12	8	11	15	15	14
21H41A0518	12	12	10	13	9	12	11	15	15	15
21H41A0519	13	13	13	11	12	13	12	15	15	15
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21H41A0521	13	12	11	15	14	13	12	9	15	15
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21H41A0528	10	9	11	10	12	13	13	9	15	10
21H41A0529	14	14	14	14	13	13	15	15	15	15
21H41A0530	9	15	10	12	13	13	14	15	15	15

5/9

67

GF GE H H

Regd. No	CN R2031051		DAA R2031052		DWDM R2031053		FMM R2031041		SPM R203105B	
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21H41A05C4	9	7	1	6	8	8	10	10	15	15
21H41A05C5	11	10	8	13	13	11	12	9	15	15
21H41A05C6	7	8	6	6	10	10	10	10	15	15
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21H41A05C8	13	14	10	12	11	10	14	15	15	15
21H41A05D0	13	14	11	10	10	10	12	9	15	15
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22H45A0505	4	7/2	3	2	9	10	11	12	15	15
22H45A0506	4	6	10	9	8	10	12	13	13	15
22H45A0507	3	7/2	3	3	8	9	11	5	13	15
22H45A0508	13	15	13	14	13	13	15	15	15	15
22H45A0509	12	14	13	12	11	13	15	13	15	15
22H45A0510	14	14	13	13	14	13	15	15	15	15
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Regd. No	CN		DAA		DWDM		OR		SPM	
	R2031051		R2031052		R2031053		R203103H		R203105B	
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216M1A0501	15	15	15	15	15	15	15	15	15	15

Signature of the Faculty:

Dept. Exams Incharge

HOD
GK
GK
Exams Incharge

Principal

BONAM VENKATA CHALAMAYYA INSTITUTE OF TECHNOLOGY & SCIENCE
DEPARTMENT OF CSE-ARTIFICIAL INTELLIGENCE AND DATA SCIENCE

Course Name: BIG DATA ANALYTICS

AY: 2023-2024

Course Code: C322

Year / Sem: III B.Tech/II Sem

Faculty Name: K.Nagendra

SCHEME OF EVALUATION WITH CO AND BT MAPPING

SNO	QUESTION	CO	BT
1.	1. Explain briefly about BDA and types of Big data with examples	C322.1	UNDERSTAND
2.	2. what is Data Stream and Explain briefly about Flajolet Martin algorithm with an example	C322.2	APPLY
3.	3. what is HDFS. Explain the architecture of HDFS?	C322.3	UNDERSTAND

1. Explain briefly about BDA and types of Big data with examples
1. explanation about BDA-2M
2. Types of Big data with examples-3M

2. what is Data Stream and Explain briefly about Flajolet Martin algorithm with an example
1. definition about Data stream-1M
2. Flajolet martin algorithm procedure-2M
3. Flajolet martin algorithm explanation-2M

3. what is HDFS. Explain the architecture of HDFS?
1. Usage of Hadoop distributed file system explanation 2M
2. Architecture and its internal components explanation 3M

Faculty Signature



K.NAGENDRA
BVC Institute of Technology & Science
BANGALORE, KARNATAKA - 560 021

BONAM VENKATA CHALAMAYYA INSTITUTE OF TECHNOLOGY & SCIENCE
Department of CSE-ARTIFICIAL INTELLIGENCE AND DATA SCIENCE

A.Y: 2023-24

Course: Big Data Analytics

Branch: CSE-AI&DS

Year: III

Semester: II

MID-1

Max Marks: 15

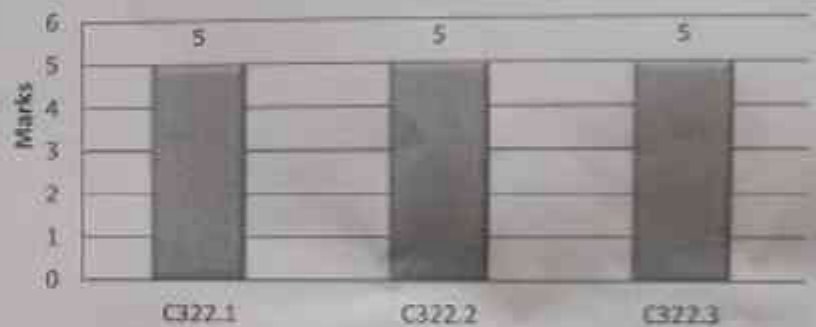
Duration: 1 1/2Hr

Q.No	Questions	Marks	CO	BL
1	Explain briefly about BDA and types of Big data with examples	5	C322.1	L1
2	what is Data Stream and Explain briefly about Flajolet Martin algorithm with an example	5	C322.2	L3
3	what is HDFS, Explain the architecture of HDFS?	5	C322.3	L1

Bloom's Level wise Marks Distribution



Course Outcome wise Mark Distribution



Course Outcome wise percentage coverage



BL – Bloom's Taxonomy Levels (L1- Remembering, L2- Understanding, L3 – Applying, L4 – Analysing, L5 – Evaluating, L6 - Creating)

CO – Course Outcomes

Faculty Signature



PRINCIPAL
 BVC Institute of Technology & Science
 BATLAPALEM, AMALAPURAM - 522 201

No	Regd. No	BE		BDA		CN		D&A		DI	
		K20204P		K20212P		K20170P		K20204P		K20204P	
		1st	2nd	1st	2nd	1st	2nd	1st	2nd	1st	2nd
		1st	2nd	1st	2nd	1st	2nd	1st	2nd	1st	2nd
1	21H41A4501	13	14	14	13	10	14	13	12	13	15
2	21H41A4502	14	11	12	13	11	13	8	10	12	12
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4	21H41A4504	11	7	13	10	9	11	13	14	12	11
5	21H41A4505	12	15	13	15	14	15	14	15	12	15
6	21H41A4506	15	15	14	15	14	15	15	14	14	15
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Regd. No	BE R200204D		BDA R200203J		CN R200202J		DAA R2002042J		DI R2002041A	
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Signature of the Faculty: *[Handwritten signatures]*
 Dept. Incharge: *[Signature]* HOD Exams Incharge: *[Signature]* Principal: *[Signature]*



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 BVC Institute of Technology & Science
 BATLAPALEM, AMALAPURAM - 535 221

Name: A.L. Shiny

Regd.: 21/11506

Date: 27/2/24 No. of Asses.

Subject: Big Data Analysis Class/Course: III CND

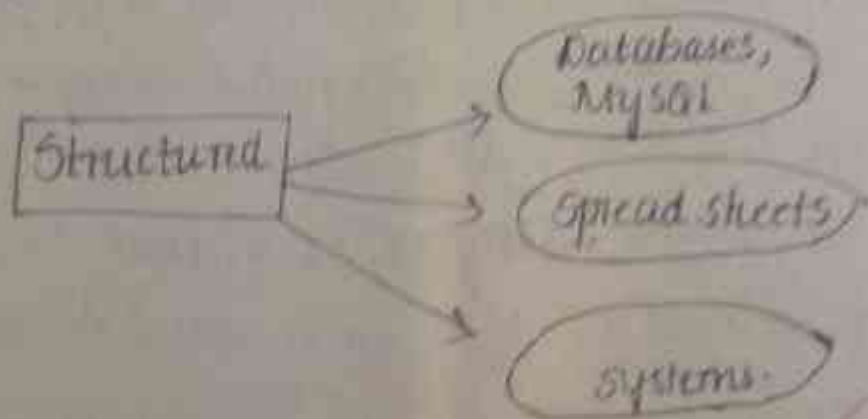
Instructor Sign

BDA:

- BDA stands for "Big Data Analysis", where it refers to the processing the high volume of data or diverse of dataset to analyze them.
- these diverse of datasets are analyzed with large technical algorithms and tools
- The Big Data Analysis required large databases where the databases required to process them must be in low latency, whereas the traditional Databases doesn't have.
- the Big Data Analysis can be classified in the types such as Descriptive Analysis, Predictive Analysis, Prescriptive Analysis.
- the Big Data Analysis is referred to the cost extensive and more effective process.
- Big Data can be of the following types
- 1) Structured
 - 2) Semi-structured
 - 3) Unstructured.
- In Big Data Analysis, the Big Data can be taken from different sources and of the different sizes

1) Structured Data

- the Structured Data refers to the well organized and well defined data.
- the Structured Data can be very easily understandable to human and also to computer processing.
- the Structured Data may not require high level methods to process. low latency methods are enough to understand them.
- the Examples of Structured Data are. Spreadsheets, Database MySQL, Systems.

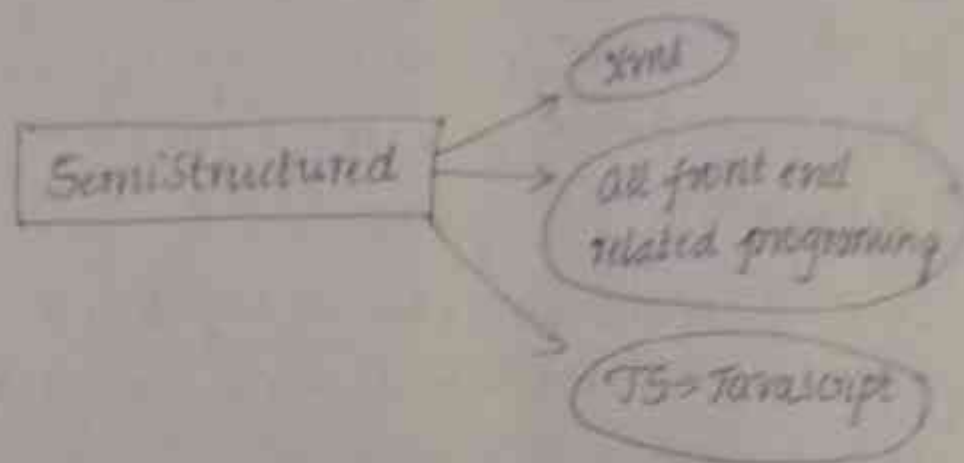


2) Semi Structured Data

- the Semi Structured Data refers to the combination of Structured and Unstructured.
- the Semi Structured Data is not well defined but it is in structured form.
- Semi Structured Data may be easily understandable for computers but ^{for} human it is bit tough to understand.

→ Semi-Structured Data can refer to the Example of Relational Database Management System, when the data is structured but not well defined.

→ Examples of semi-structured data are:



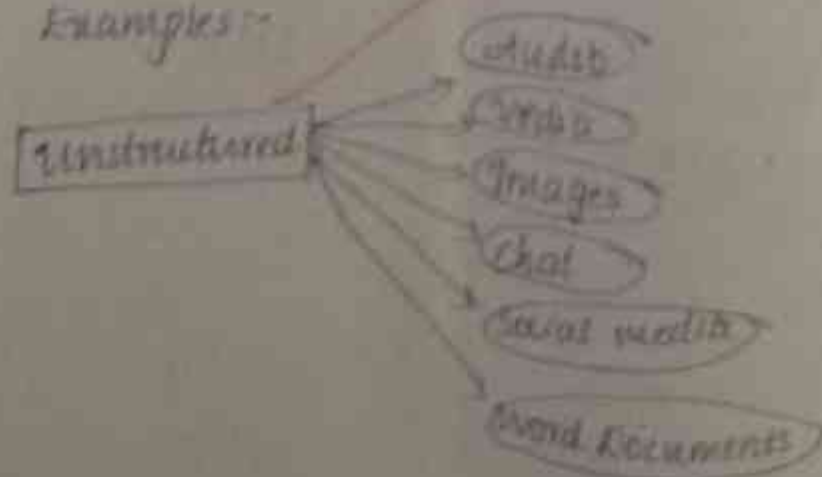
③ Unstructured Data:-

→ Unstructured Data refers to unorganised and not well defined Data.

→ This type of Data is very hard to understand by the Computers and humans.

→ Unstructured Data refers to more complex Data and less efficiency but now a day more organisations make use of unstructured Data.

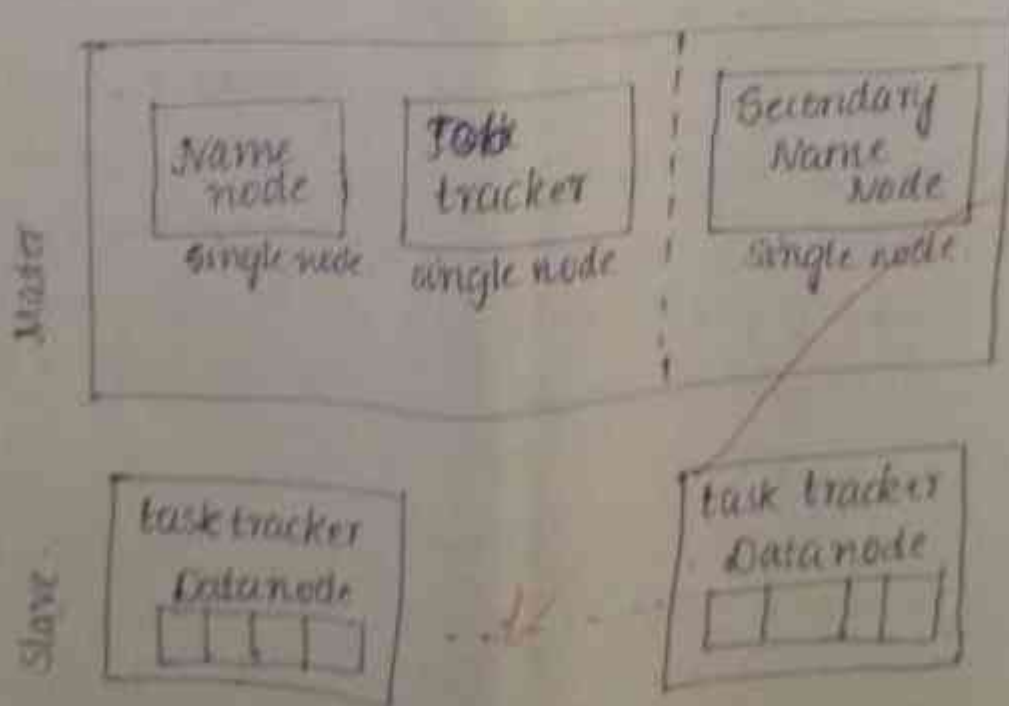
→ Examples:-



3)

HDFS

- HDFS stands for "Hadoop Distributed File System", where, hadoop refers to the framework, that can be implemented by "Java".
- Hadoop was introduced by "cutting & Cofferella".
- Hadoop combines the Distributed file system, which is the place where large volume of data can be stored, refers to the "Hadoop Distributed file system".
- In HDFS Architecture, the hadoop was found by the google through GFS, so, based upon this hadoop was implement.
- In HDFS architecture, it consists of Master and slave nodes.



- the Architecture contains single Master node and one or more slave nodes.

→ the Master node contains the 1) Name Node
2) Job tracker
3) Secondary Name Node.

1) Name Node:

→ the name node is used to perform the execution of operations of file system such as reading, writing, deleting and retrieving.

→ the name node is attached with job node

→ The job of name node is to set the key value to identify the data.

2) Job tracker:

→ the job tracker make processing of the operations of name node.

→ the job tracker takes tasks from the name node.

→ the name node ^{containing} refers to meta data which is data about data.

3) Secondary Name Node

→ which is used to control the name node tasks & operations

→ which do not have access of write operation.

- the slave node contains
- 1) Data Node
 - 2) Task tracker

1) Data Node :-

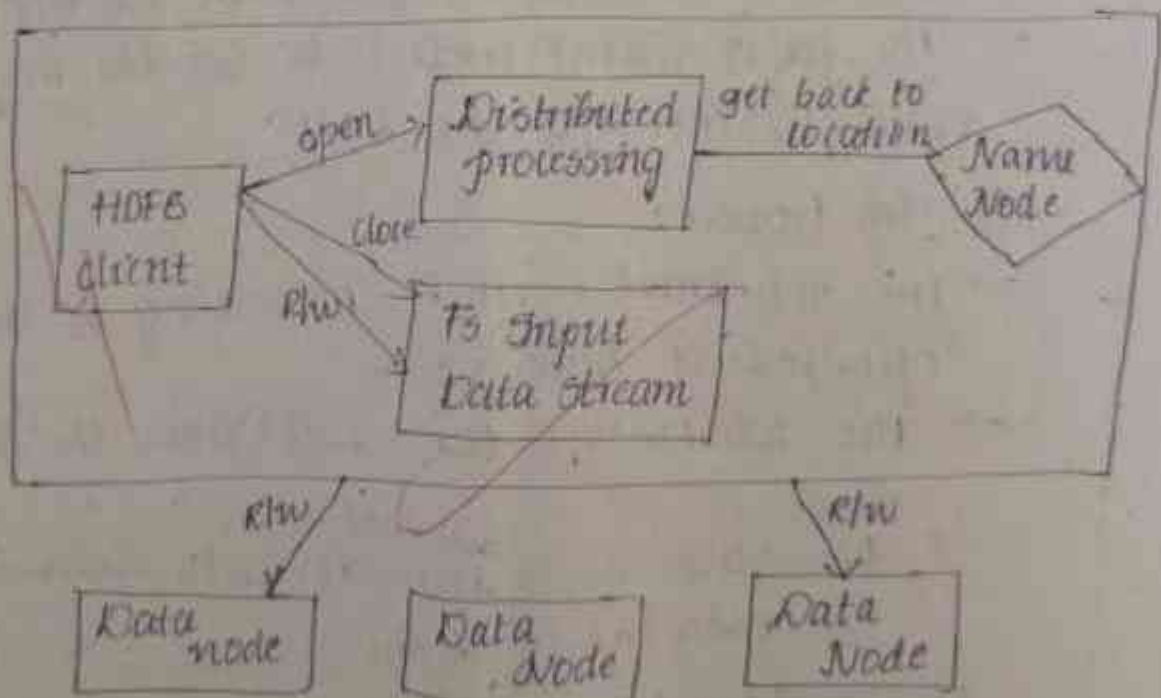
→ which is used to store the data of operations done on hadoop cluster

2) Task tracker :-

→ which is on the basis of job tracker, which sets the path of tasks that have to be performed by the job tracker.

→ then after applies to link to files.

Read & write node of HDFS:



Write Operation

→ the Hadoop file system will make use of job tracker and perform operation based upon it and after it sends to store to link to files.

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- the read operation, have only access to read the files. It does not make use of job tracker
- But, it make use of task tracker to read the data from data nodes.

2) Data Stream:

- Streaming of Data refers to the data of large volume and "diverse of Data sets". While processing these type of Dataset, it require the methods of large Algorithms and "low-latency" processes.

Example → Data of Ecommerce website, facebook.

Flajolet Martin Algorithm:

- the Flajolet Martin Algorithm refers to find the distinct number of elements in the given Universal set by using "hash functions" to set bit string of Data.
- Initially, we before finding to no. of distinct elements, we find the upper boundary of distinct elements.
- the upper boundary of distinct elements must be in less size. Should not exceeds the maximum of universal set.

→ we need an array of string initially assigned to zero.

→ Now, by using hash functions we need to find the input and now that input is set to the number link to bit string.

→ the number is set with k^{th} bit of the given set.

→ finally, we count the trailing zeros and find the distinct no. of elements.

Steps:

1) Initially, the array of distinct elements Stream Dataset 'S' and max is assigned to 0.

2) Now, we will find the hash function to each element.

3) Now, convert the hashed function elements to binary values.

4) Now, count the no. of trailing zeros and assign to 'n'.

if ($n > \text{max}$)

$\text{max} = n$,

5) Now, find the distinct element by using the formula (2^n) .

Example:

let us consider the stream data

1, 3, 2, 1, 4, 3, 4, 3, 1, 2, 3, 1.

hash function $h(x) = (6x+1) \bmod 5$.

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(Signature)

Now, perform hash operations on each element.

$$h(0) = (6(0)+1) \bmod 5$$

= 1 \longrightarrow binary value = 010 \rightarrow trailing zeros = 1

$$h(3) = (6(3)+1) \bmod 5$$

= 4 \longrightarrow 100 = 2

$$h(2) = (6(2)+1) \bmod 5$$

= 5 \longrightarrow 011 = 0

$$h(2) = (6(1)+1) \bmod 5$$

= 2 \longrightarrow 010 = 1

$$h(2) = (6(2)+1) \bmod 5$$

= 3 \longrightarrow 011 = 0

$$h(3) = (6(2)+1) \bmod 5$$

= 4 \longrightarrow 100 = 2

$$h(4) = (6(4)+1) \bmod 5$$

= 0 \longrightarrow 000 = 0

$$h(3) = (6(2)+1) \bmod 5$$

= 4 \longrightarrow 100 = 2

$$h(1) = (6(1)+1) \bmod 5$$

= 2 \longrightarrow 010 = 1

$$h(2) = (6(2)+1) \bmod 5$$

= 3 \longrightarrow 011 = 0

$$h(3) = (6(3)+1) \bmod 5$$

= 4 \longrightarrow 100 = 2

$$h(1) = (6(1)+1) \bmod 5$$

= 2 \longrightarrow 010 = 1

Therefore, the max trailing zeros is 2

$$n = 2, \text{ where } \text{max} = 0.$$

$\therefore n > \text{max}$
then $(\text{max} = 2)$

Now, to find distinct no. of elements

we use λn

$\Rightarrow \lambda(2)$

$\Rightarrow 4$

Hence, we have '4' distinct no. of elements
in the given Data Stream.

BONAM VENKATA CHALAMAYYA INSTITUTE OF TECHNOLOGY & SCIENCE
DEPARTMENT OF ARTIFICIAL INTELLIGENCE & MACHINE LEARNING

A.Y: 2023-24

Course: DL MID-2

Max Marks: 15

Branch: AI&ML

Year: III

Semester: II

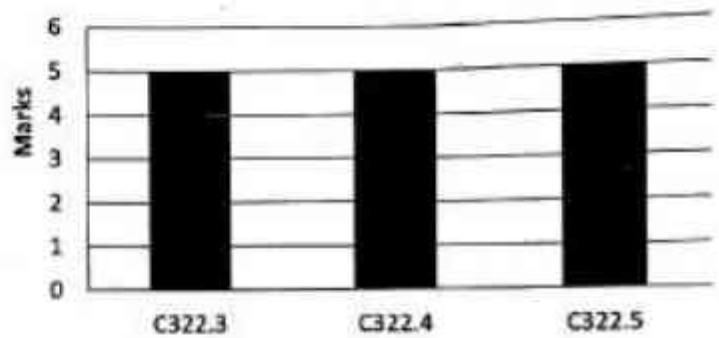
Duration: 1.5Hr

Q.No	Questions	Maks	CO	BL
1	Explain the relationship between the network, layers, loss function, and optimize	5	C322.3	L2
2	Illustrate the process of building a deep neural network in PyTorch	5	C322.4	L2
3	Discuss about Restricted Boltzmann Machines.	5	C322.5	L2

Bloom's Level wise Marks Distribution



Course Outcome wise Mark Distribution



BL – Bloom's Taxonomy Levels (L1- Remembering, L2- Understanding, L3 – Applying, L4 – Analysing, L5 – Evaluating, L6 - Creating)

CO – Course Outcomes

Bonam Venkata Chalamayya Institute of Technology & Science
DEPARTMENT OF ARTIFICIAL INTELLIGENCE & MACHINE LEARNING
Scheme of Evaluation With CO and BT Mapping

Course: DL (C322)

Class: III B.Tech II Sem

AY: 2023-24

SCHEME OF EVALUATION WITH CO AND BT MAPPING

SNO	QUESTION	CO	BT
1.	Explain the relationship between the network, layers, loss function, and optimizer	C322.3	Understanding
2	Illustrate the process of building a deep neural network in PyTorch	C322.4	Understanding
3	Discuss about Restricted Boltzmann Machines.	C322.5	Evaluating

1. Explain the relationship between the network, layers, loss function, and optimizer

1. Diagram ----2m
2. Explanation----3m

2. Illustrate the process of building a deep neural network in PyTorch

1. list of 5steps --1m
2. Explanation----4m

3. Discuss about Restricted Boltzmann Machines

1. Definition --2m
2. Explanation----3m



3. Ans Restricted Boltzmann Machines

$4+5+5=14$

Boltzmann Machines

→ Usually all the models in deep learning or in Machine Learning are the Supervised Models & Unsupervised Models.

Supervised Models are:

Artificial Neural Networks (ANN)

Convolutional Neural Networks (CNN)

Recurrent Neural Networks (RNN)

Unsupervised Models are:

Boltzmann Machines

Auto encoders

→ Boltzmann Machines are again classified into two types

① Restricted Boltzmann Machines (RBM)

② Deep Belief Network (DBN)

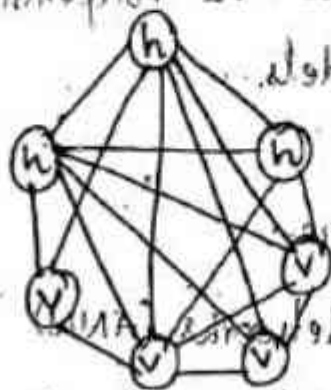
① Restricted Boltzmann Machines (RBM):

Restricted Boltzmann Machines is a Unsupervised

Models.

→ Restricted Boltzmann Machines, every node is connected to every other node.

→ In Restricted Boltzmann Machines, there are hidden nodes and visible nodes.



→ The above diagram represents Restricted Boltzmann Machines.

here h represents hidden nodes
 v represents visible nodes

→ hidden nodes are connected to visible nodes in a bidirectional manner (it is not a directed).

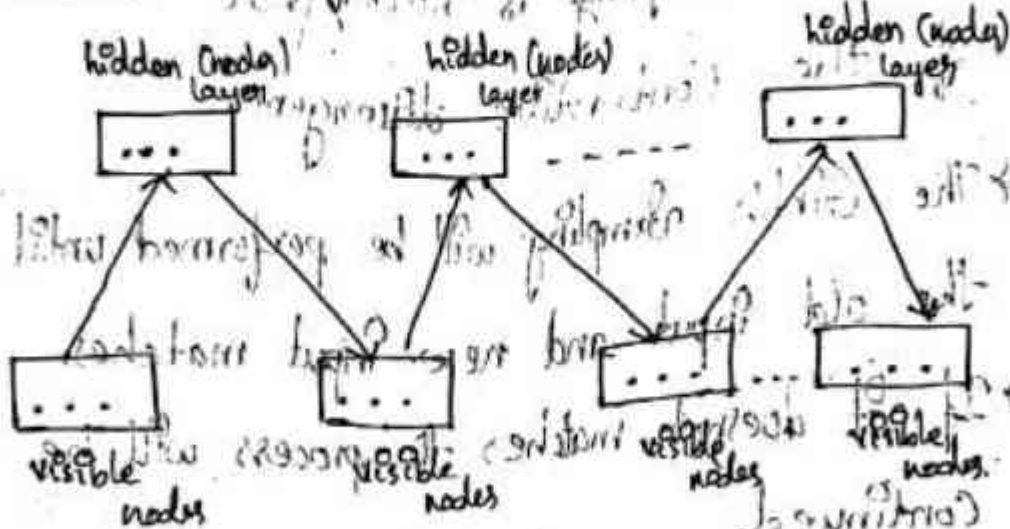
→ hidden nodes are connected to visible nodes.

→ visible nodes are connected to hidden nodes.

RBM Training:

① Contrastive divergence

② Gibbs Sampling



→ Here Hidden nodes are not connected to visible nodes and visible nodes are not connected to visible nodes (They connect each other).

③ Contrastive Divergence:

→ In Contrastive Divergence the weights are measure

→ Here, the input layer will be updated.

→ Here, the hidden layer forms with the help of visible layers.

→ The first input layer is not matches with

with the updated input.

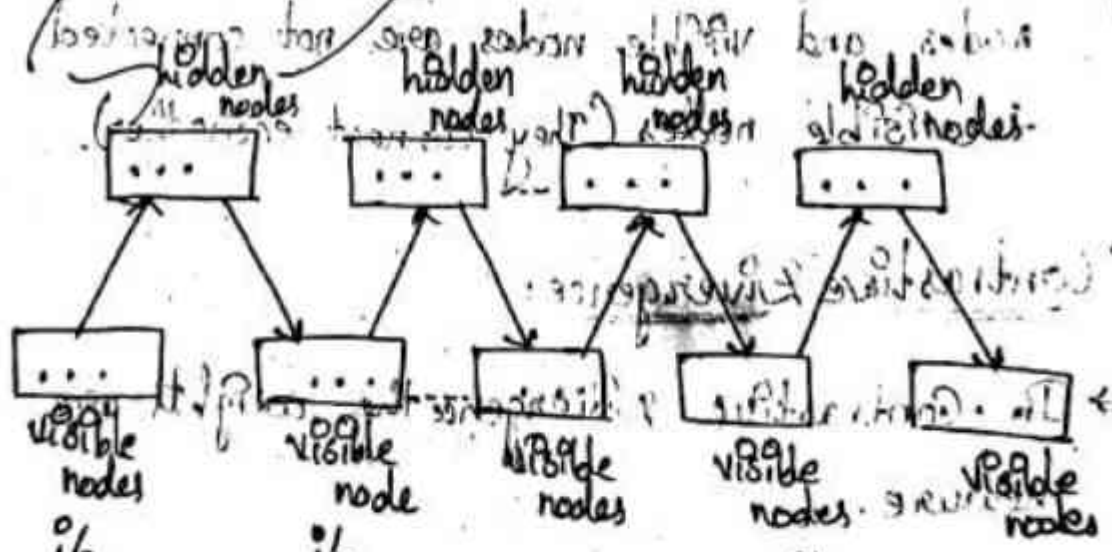
② Gibb's Sampling:

→ Gibb's Sampling is nothing but Continuation of the Contrastive Divergence.

→ The Gibb's Sampling will be performed until the old input and new input matches.

→ If it does not matches the process will be Continued.

→ If it matches the process will be stopped.



i/p

i/p

i/p

i/p

does not match

→ The process will be continued.

matched

→ The process will be stopped

Contrastive

divergence

Gibb's

Sampling

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Regd. No.: 21H41AG130

Subject:

Instructor Sign:

Q. Ans Building a deep neural network in PyTorch:

→ Deep Neural Network is a deep Learning Technique.

⇒ It is used to solve complex problems.

→ PyTorch is a Deep Learning Framework.

→ PyTorch Framework is mainly used for Solving problems and it is speed.

→ There are five steps to build a deep neural network in PyTorch:

① Import necessary modules

② Design a network Architecture

③ Initialize parameters

④ Create the Data loader.

⑤ Train the Network

① Import necessary Modules

→ It is first step for building the deep neural network using PyTorch

→ Import necessary Modules is nothing but importing the modules which are used for the building of deep neural network

② Design a Network Architecture

→ It is the second step for building the deep neural networks using PyTorch

→ To design a Network Architecture we use layer like activation layer (like relu), network layer, Pooling and other...

③ Initialize Parameters

→ It is the third step for building the deep neural networks using PyTorch

→ Here, we initialize the parameters that we need for the further steps

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④ Create the Dataloader

→ It is the fourth step to build the deep neural network using pytorch

→ Here we load the dataset and that dataset → dataloader

→ After loading the dataset we train the network.

⑤ Train the Network

→ It is the fifth step to build a deep neural network using pytorch.

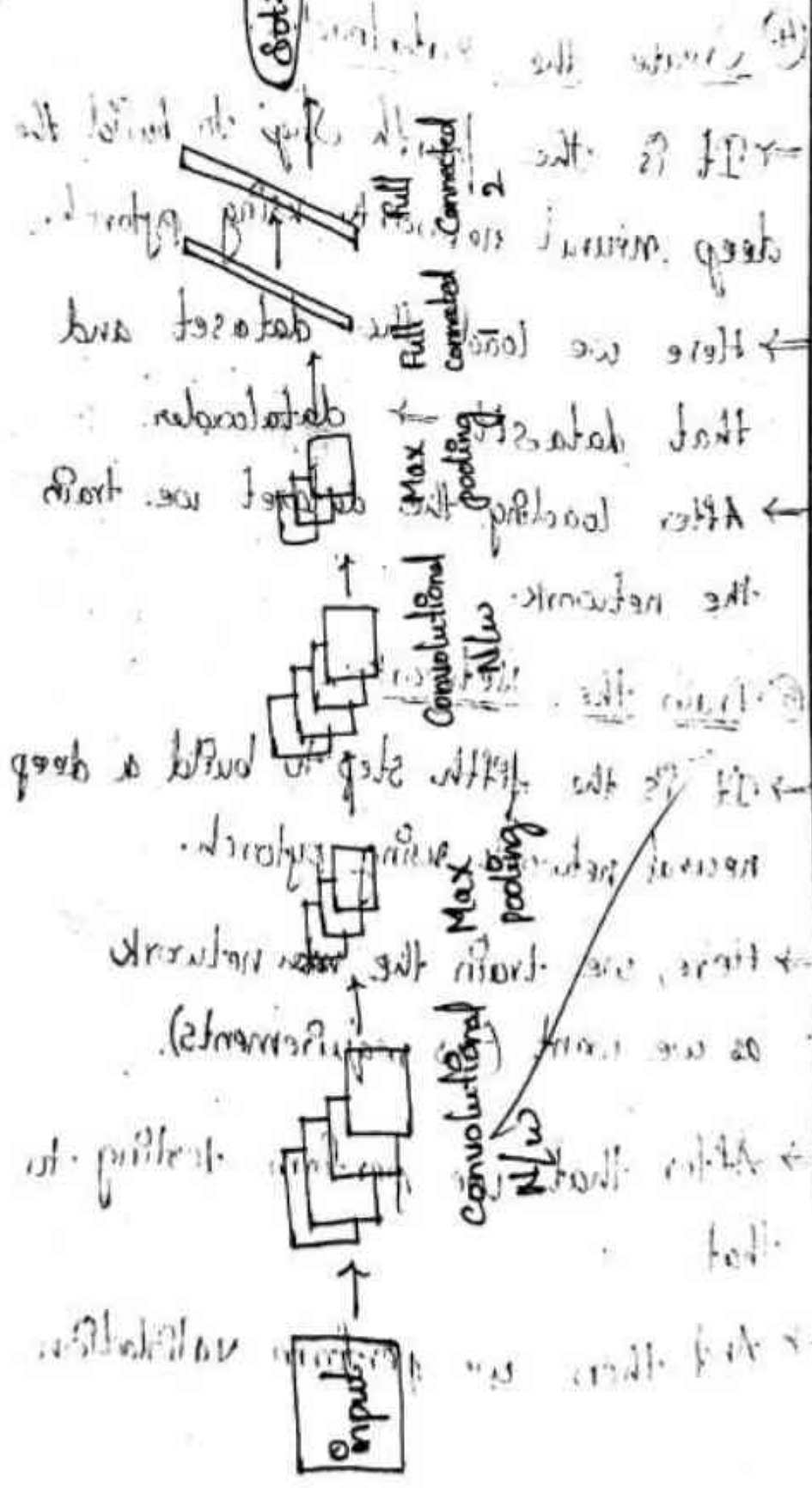
→ Here, we train the network as we want (as requirements).

→ After that we perform testing to that

→ And then we perform validation.

REVISION

Softmax




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Ans:

Relationship between Network, Layers, Loss function and optimizers

Network:

→ Network is used for deep learning Algorithms as well as Machine learning Algorithms

Layers

→ There are so many network layers like CNN (convolutional Neural Network), ANN (Artificial Neural Network), RNN (Recurrent Neural Network).

Layers:

→ Layers are used for processing the data (hidden layer)

→ There are so many layers → activation layers (like relu), Network layers ---

Loss function:

- If the accuracy is low the loss function is high.
- Loss function is difference b/w the actual value and the predicted value.
- If the predicted value and actual value is not same then the loss function will be high.

→ If the actual value and predicted value is then the loss function is low.

Optimizer:

- Optimizer is used for optimizes.
- Optimizer gives weights and bias as shown in the below diagram.

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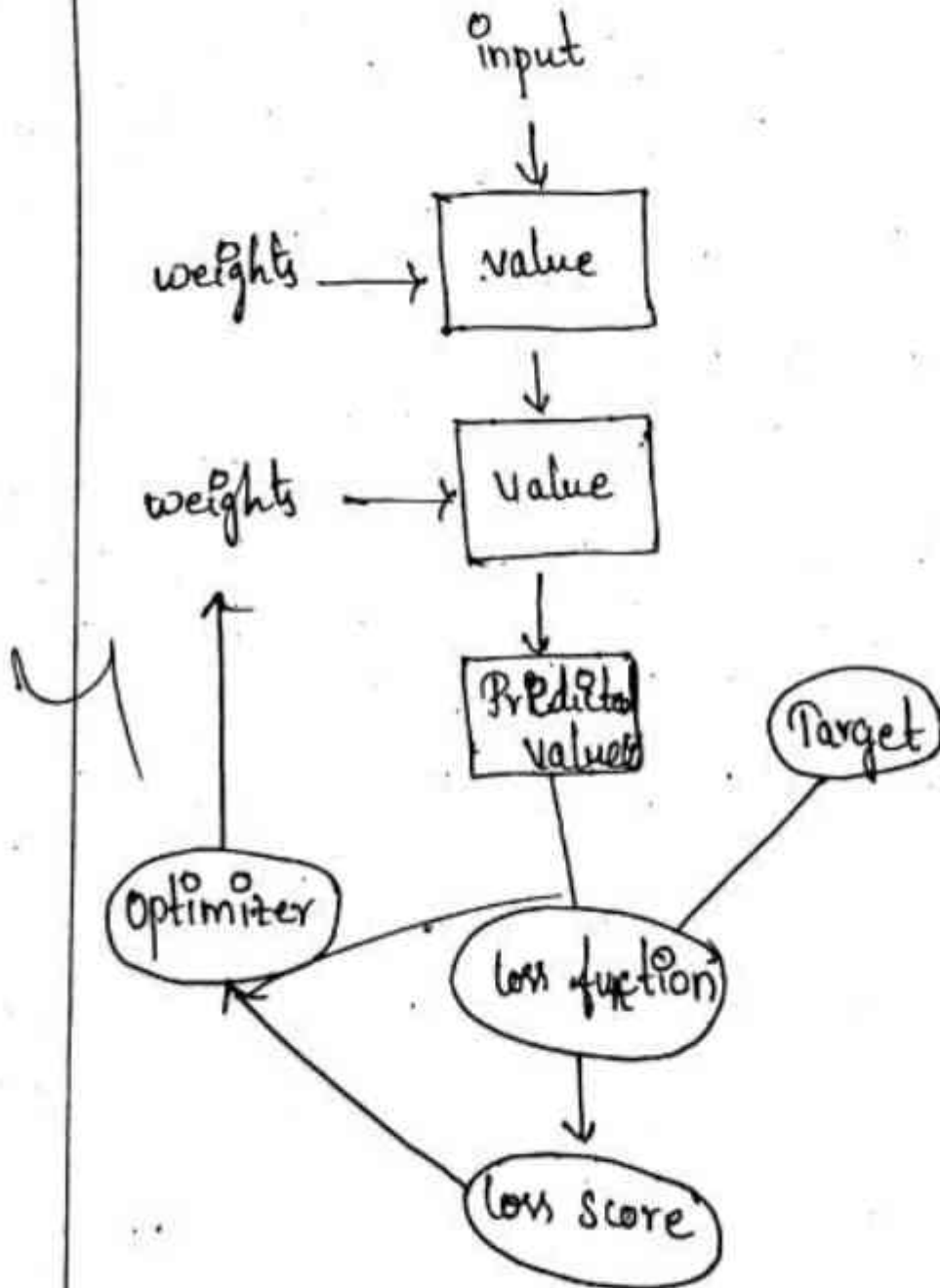
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Relationship loss function and optimizer:



KP

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S No	Regd. No	BE		IOT		CN		DL		DAA	
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60	21H41A6161	14	12	13	11	12	14	15	14	11	5
61	21H41A6162	12	14	14	12	14	14	9	15	13	12
62	21H41A6163	9	15	10	13	11	14	12	14	13	13
63	21H41A6164	9	13	10	10	12	10	10	9	12	11
64	21H41A6165	14	14	13	11	13	14	13	13	13	15
65	21H41A6166	13	14	13	15	13	15	12	14	11	10
66	22H45A6101	12	13	15	14	9	14	10	13	12	12
67	22H45A6102	7	11	11	12	9	11	9	12	9	3
68	22H45A6103	13	15	15	14	14	14	15	15	13	15
69	22H45A6104	4	4	7	9	7	8	9	9	10	8
70	22H45A6105	12	10	15	10	9	13	13	12	11	8
71	22H45A6106	13	15	15	11	11	12	11	14	14	12

Signature of the Faculty:

Dept. Exams Incharge

HOD

Exams Incharge

Principal

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B V C INSTITUTE OF TECHNOLOGY & SCIENCE:: BATLAPALEM

MID EXAM - I

II-MBA (IV SEM)

SUB: I E

TIME: 10.00A.M to 11.30 A.M DATE: 27-02-2024

MAX MARKS: 15

ANSWER ALL THE QUESTIONS.

3X5=15M

- 1 Explain about Entrepreneurial motivation and barriers? (C222.1- Understanding)
2. What is meant by feasibility study ? Explain its types and techniques?(C222.2 - Remembering)
3. Outline institutional support for new ventures?(C222.3- Understanding)

Radha



W

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BATLAPALEM, AMALAPURAM - 533 221

Bonam Venkata Chalamayya Institute of Technology & Science
Department of Management studies(MBA)

Course: INNOVATION AND ENTREPRENEURSHIP
AY: 2023-24 ; 4th semester

Class: II MBA
Faculty name: V.Padmasri

Course code:C222

SCHEME OF EVALUATION WITH CO AND BT MAPPING

QNO	QUESTION	MARKS	CO	BT LEVEL
1	Explain about Entrepreneurial motivation and barriers?	5	C222.1	TL.2
2	What is meant by feasibility study ? Explain its types and techniques?	5	C222.2	TL.1
3	Outline institutional support for new ventures?	5	C222.3	TL.2

1. Explain about Entrepreneurial motivation and barriers?

Entrepreneurial motivation -2m

Entrepreneurial motivation and barriers-3m

2. What is meant by feasibility study ? Explain its types and techniques?

Feasibility study -1m

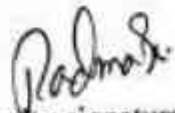
Types 2m

Techniques 2m


3.Outline institutional support for new ventures?

New venture meaning -1 m

Institutional support for new ventures 4M


Faculty signature




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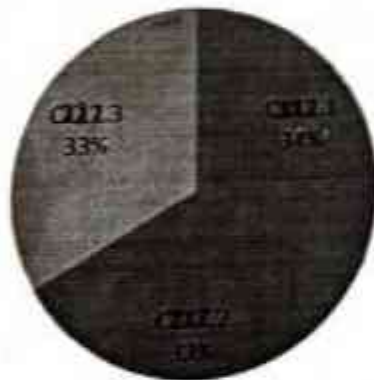
Bonam Venkata Chalamayya Institute of Technology & Science
Department of Management studies(MBA)

Course: INNOVATION AND ENTREPRENEURSHIP (C222) Class: II MBA
AY: 2023-24 ; 4th semester

INTERNAL EXAMINATION - I

QNO	QUESTION	MARCS	CO	BT LEVEL
1	Explain about Entrepreneurial motivation and barriers?	5	C222.1	TL2
2	What is meant by feasibility study ? Explain its types and techniques?	5	C222.2	TL1
3	Outline institutional support for new ventures?	5	C222.3	TL2

CO COVERAGE



Blooms Taxonomy coverage



BL – Bloom's Taxonomy Levels (TL1- Remembering, TL2- Understanding, TL3 – Applying, TL4 – Analysing, TL5 – Evaluating, TL6 -Creating)


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Name: Ch. Sivaburayudhi
Subject: IE

MAIN ANSWER SCRIPT
Regd.: 22NH1E0007
Class/Course: MBA

Date: 23/10/24 No. of Atts.:
Inspirator Sign: [Signature] 5/5/24

1. Entrepreneur :-

Entrepreneur means the person who start a business in a innovative way and creativity of new thinking that person called entrepreneur.

Entrepreneurship :-

Entrepreneurship means the process of enterpriser doing business in innovative way and taking initiation of reach & success of those goals.

Entrepreneurial Motivation :-

The person who inspired & taken intion by the giving of motivation & teaching to the behaviour of Entrepreneurial goal.

Entrepreneur is a business man a person who takes the business intiation in the innovative way that creation of skills called entrepreneurship.

Barriers of entrepreneurial motivation

The Entrepreneurial Motivation must occur of different barriers so that divided into three types as follows.

→ need of lack of motivation and, lack of patience and, lack of depend on other activities.

Social Barriers :-

Entrepreneurial motivation point of view of social barriers that are related out of entrepreneurship

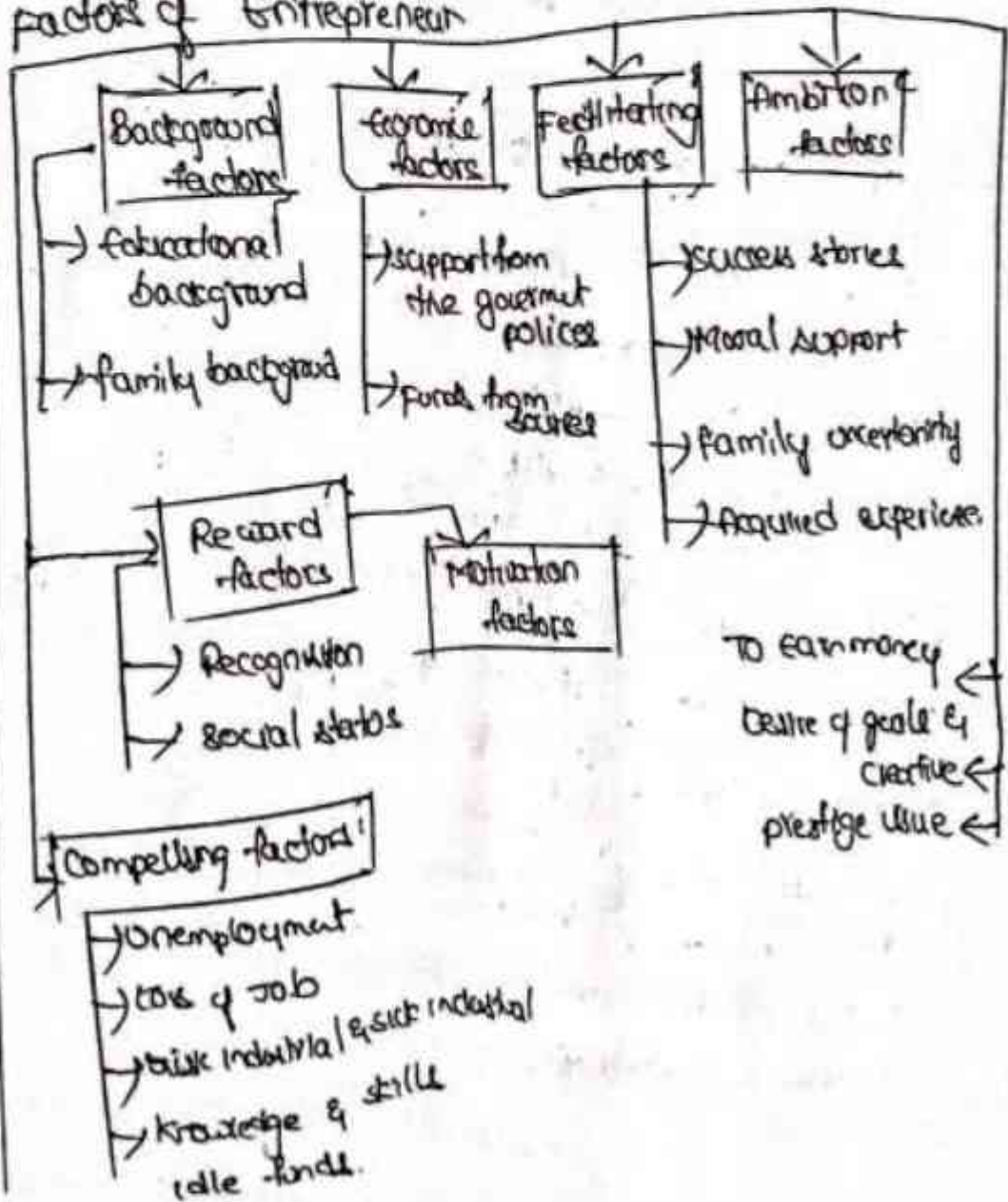
(a) pressure from community :-

The barrier may come in the community of person they see there points that cause a problem to entrepreneur.

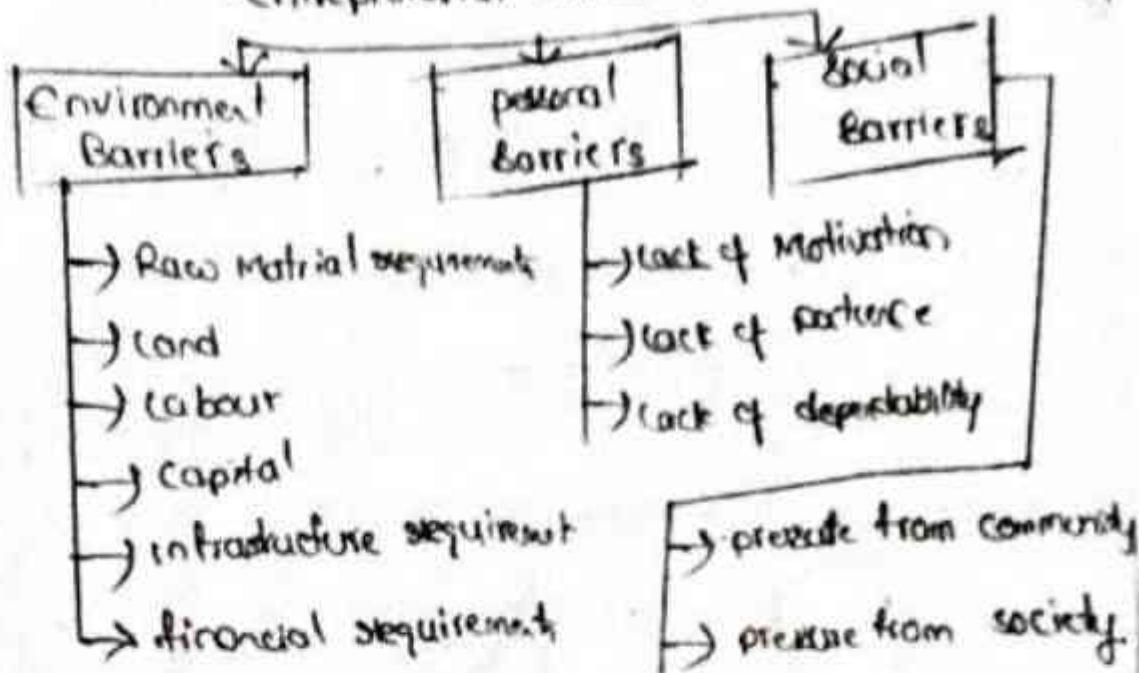
(b) pressure from society :-

The barrier may arise in the society point they feel that are not suppose to do business.

Factors of Entrepreneur



Entrepreneurial Motivation Barriers



(1) Environmental Barriers:-

Environmental barriers nothing but the environmental problems which comes from out of business as below

(a) Raw material

- in entrepreneurship availability of raw material were of barrier.

(b) Land, Labour, Capital:-

Land, Labour, Capital most wanted things to business. Most required for own business.

(c) Infrastructural requirements:-

Infrastructural means the furniture for production.

(d) Financial requirements:-

Most important thing of finance related.

(2) Personal Barriers:-

While starting of business the personal problems may arise that as follows

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M B A IV SEM FINANCE I MID & MINI PROJECT MARKS (22 BATCH)

THEORY & MINI PROJECT

Sl. No	Regd No	MID 1	M P 1	MID 1	M P 1	MID 1	M P 1	MID 1	M P 1	MID 1	M P 1	MID 1	M P 1
		SCMA		IAE		FD		GFM		FRM		SFM	
		MB1941		MB1942		MB1943		MB1942		MB1943		MB1944	
		M.M: 15	M.M: 10	M.M: 15	M.M: 10	M.M: 15	M.M: 10	M.M: 15	M.M: 10	M.M: 15	M.M: 10	M.M: 15	M.M: 10
1	22H41E0001	14	10	14	10 ✓	12 ✓	10 ✓	14	10	12 ✓	10 ✓	14	9 ✓
2	22H41E0003	8	10	7	9 ✓	10 ✓	8 ✓	12	9	9 ✓	8 ✓	11	7 ✓
3	22H41E0004	13	10	14	10 ✓	9 ✓	8 ✓	13	10	9 ✓	8 ✓	14	9 ✓
4	22H41E0005	14	10	13	9 ✓	12 ✓	10 ✓	14	10	12 ✓	10 ✓	13	10 ✓
5	22H41E0006	14	10	12	8 ✓	12 ✓	8 ✓	14	10	13 ✓	8 ✓	12	9 ✓
6	22H41E0007	13	10	14	10 ✓	13 ✓	10 ✓	14	10	13	10	14	10 ✓
7	22H41E0008	8	10	12	8 ✓	12 ✓	8 ✓	14	9	11 ✓	8 ✓	13	7 ✓
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10	22H41E0015	13	10	12	8 ✓	12 ✓	10 ✓	14	10	12 ✓	10 ✓	14	9 ✓
11	22H41E0017	-1	-1	-1	-1 ✓	-1	-1	-1	-1	-1	-1	-1	-1 ✓
12	22H41E0018	14	10	12	9 ✓	13 ✓	10 ✓	15	10	14 ✓	10 ✓	13	10 ✓
13	22H41E0019	12	10	12	8 ✓	13 ✓	10 ✓	14	10	13 ✓	10 ✓	14	9 ✓
14	22H41E0020	13	10	10	9 ✓	12 ✓	10 ✓	13	10	12 ✓	10 ✓	13	9 ✓
15	22H41E0021	14	10	12	8 ✓	12 ✓	10 ✓	14	10	12 ✓	10 ✓	14	9 ✓
16	22H41E0022	14	10	12	8 ✓	13 ✓	10 ✓	14	10	12 ✓	10 ✓	14	9 ✓
17	22H41E0029	14	10	12	9 ✓	13 ✓	10 ✓	15	10	12 ✓	10 ✓	14	9 ✓
18	22H41E0030	12	10	12	8 ✓	13 ✓	10 ✓	14	10	12 ✓	10 ✓	13	9 ✓



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Radhika



BONAM VENKATA CHALAMAYYA INSTITUTE OF TECHNOLOGY & SCIENCE
AMALAPURAM -533221
(AUTONOMOUS)

Mid Exam: II
Subject: HCI

A. Y. 2023-24
Max. Marks: 40

Branch: MCA
Times: 2Hr

Answer all questions

4 x 10 = 40

Q.No.	Question	Marks	CO	BL
1	Explain about Key aspects of Screen Navigation and flow in Screen Designing?	10	CO3	BL5
2	a) Explain a detailed note on selection of devices based and Screen-Based controls. b) What are the benefits of Icons and Indicators in Windows?	10	CO4	BL5
3	Discuss about HCI in the Software Specification Methods.	10	CO5	BL2
4	a) Explain about Types of Pointing Devices. b) Summarize the Image and Video Displays.	10	CO6	BL4



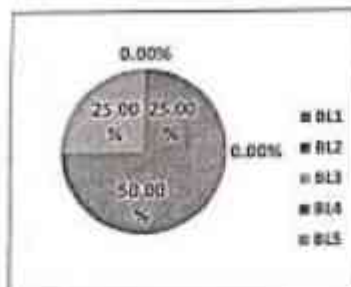
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FACULTY SIGNATURE
B. S. P.

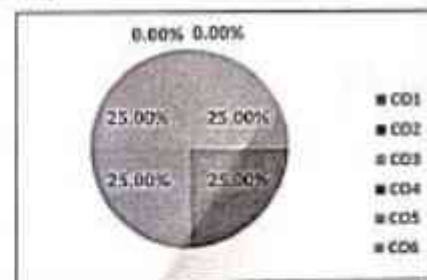
**BONAM VENKATA CHALAMAYYA INSTITUTE OF TECHNOLOGY &
SCIENCE(AUTONOMOUS):: AMALAPURAM
MID EXAMINATIONS QUESTION PAPER**

Branch: MCA		Class: I YEAR II SEM		
SUB: HCI				
Q.No	Question	MARKS	CO	BL
1	Explain about Key aspects of Screen Navigation and flow in Screen Designing?	10	CO3	BL4
2	a) Explain a detailed note on selection of devices based and Screen-Based controls. b) What are the benefits of Icons and Indicators in Windows?	10	CO4	BL5
3	Discuss about HCI in the Software Specification Methods,	10	CO5	BL2
4	a) Explain about Types of Pointing Devices. b) Summarize the Image and Video Displays.	10	CO6	BL4

BL-OK Accepted...



CO-OK Accepted...



BL1	BL2	BL3	BL4	BL5
0	0	0	10	0
0	0	0	0	10
0	10	0	0	0
0	0	0	10	0
0	10	0	20	10
0.00%	25.00%	0.00%	50.00%	25.00%

25.00%

CO1	CO2	CO3	CO4	CO5	CO6
0	0	10	0	0	0
0	0	0	10	0	0
0	0	0	0	10	0
0	0	0	0	0	10
0	0	10	10	10	10
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100.00%




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INTERNAL THEORY EXAMS MAIN ANSWER BOOK

Year 1st B.Tech/M.Tech/MCA/MBA 2nd Semester, Mid Exam Fac 05 Date 03.05.2024
 Branch MCA Subject Name HCZ Branch Code 00
 Name of the Student Sk. Masthama Beebi Regd No 23H41F0040

Sk. Masthama
03/05/24
 Signature of the Student with date

No. of Additional Sheets attached
 In Figure 06
 In Words Six

[Signature]
 Signature of the Evaluator with date

Short Answer Questions : (For Evaluator's award only)

Q.No.	I-a	I-b	I-c	I-d	I-e	Total
Marks						

Subjective Questions : (For Evaluator's award only)

Q.No.	1				2				3				4				Total
	a	b	c	d	a	b	c	d	a	b	c	d	a	b	c	d	
Marks	10				9				5	5			5	5			39

Short Answer Questions Marks	Subjective Test Marks (Scaled)	Grand Total
		<u>29</u>

[Signature]
Signature of the Evaluator with date

- Instructions to the Candidate :
- These Marks will be considered for Internal Marks
 - Write Answer legibly on both side of paper indicating the question number and its sub number
 - Attach Additional Sheets, Graph sheets etc to the main answer book securely
 - The Answer Book should be handed over the Invigilators before leaving the Examination Hall

1. Ans Importance of the User Interface :-

- The importance of the user interface lies in a critical role in shaping the overall user experiences with the digital system.
- User Satisfaction :-
- 9.1 Usability and efficiency
- Productivity and Task Completion
- Receiving training and support
- Brand perception and loyalty
- Accessibility and inclusive
- Competitive Advantages



- User engagement and retention
- User-feedback and iterative improvements
- Adoption and Acceptance

• User Satisfaction :-

- A user-friendly UI provides User Satisfaction.
- When a user find the easy way to navigate, interacts with the system.

• Usability and Efficiency :-

- An effective UI helps users to do things in a quick and easy.

• Productivity and Task Completion :-

- A well-structured UI helps users to get things done faster and with fewer errors.

• Reducing Training and Support :-

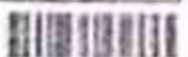
- A user-friendly UI builds the positive meaning less need for training and keep users coming back and customer support.

• Brand perception and Loyalty :-

- A user-friendly UI builds the positive image of the brand and keep users coming back.

• Accessibility and Inclusive :-

- An Accessible UI welcomes all users regardless of their capability.



• Competitive Advantages :-

- A superior UI provides a product an edge over the competitors.

• User engagement and retention :-

- An engaging UI keeps the user interested and coming back for more.

• User feedback and iterative improvements :-

- A good UI allows users to provide feedback and make improvements.

• Adoption and Acceptance :-

- A user-friendly UI encourages users to accept and use other technologies.

• Great designs :-

- Enhance User Satisfaction and Experience
- Improved Usability and Efficiency
- Positive Brand perception and image
- Competitive advantages in the market.
- Increase user engagement and retention.
- Accessibility for the broader user base.
- Fosters innovation and Creativity
- Cost effect in the long run.

• Competitive Advantage :-

- A superior in products a market an exp over the competitors.

• User engagement and retention :-

- An expert in users - the user interested and coming back for more.

• User feedback and iterative improvements :-

- A good in allows users to provide feedback and make improvements.

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- positive Brand perception and image
- Competitive advantages in the market.
- Increase User engagement and retention.
- Accessibility - for the broader user base.
- -Fosters innovation and Creativity
- Cost effect in the long Run.



2. Q.1 • Graphical System :-

~ Graphical System refers to a Computer based System that utilizes the graphical elements like icons, images, charts, visual representation. present and interactive with the information and data.

~ Graphical System is represented as a Graphical User Interface (GUI) which provides the visual intuitive and way to navigate the Operating System.

• Characteristics of a Graphical System :-

- Visual Representation
- Graphical User Interface
- Interactive Elements
- Immediate feedback
- Continuously Representation
- User-friendly Design
- Data visualization
- Multimedia Controls
- Contextual menus
- What you see is what you get.

9

• Visual Representation :-

• Information and data present using graphical elements like icons, charts, images, multimedia.

• Graphical User Interface :-

~ Graphical user interface provides user interface and allows to interact with the graphical elements through links, gestures and other input methods.

• Interactive elements :-

• Users can directly manipulate of the elements, such as dragging, rotating and resizing them.

• Immediate feedback :-

• Users receive visual instant feedback while interacting with the graphical elements.

• Continuous Representation :-

• Users on the screen correspond directly underlying the content or data, changing in the object and reflects changes in the data.

• A user-friendly design :-

• Graphical System aims intuitive the easy to use, navigation Reduced learning Curve for users.



• Visual Representation :-

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• A User-friendly Design :-

• Graphical System aims inclusive the easy to use, navigation reduces learning curve for users.



• Data Visualization :-

- The system provides the complex data using icons, images, (a) visual representation - formats - for better understanding.

• Multimedia Supports :-

- The system handles the multimedia contents like images, audios and videos.

• Contextual menus :-

- The graphical system provides the contextual menus with relevant options based on the user's interaction.

• What you see is what you get :-

- User's sees a real-time representations of their work during the editing and design process.



Imp: (a)

• Human Interaction With Computers :-

- Human interaction with computers is also known as Human Computer Interaction (HCI).
- It is a process in the process of user interacting with a digital system and technology through the various input and output methods.

• Input method :-

- Users interact with the computers through various input devices such as keyboard, mouse, touch pad, voice recognition and gestures, motion sensors.

• Output method :-

- Computer provides the information and data in a feedback to users through the output devices. Such as screens, speaking, haptic feedback and visual indicators.

• Graphical User Interface :-

- It uses visual interfaces icons, images, buttons allow users to interact with the computer application and digital systems.



• Natural language processing (NLP) :-

- Natural language processing allows users to interact with the Computer using natural language commands and response.
- As seen in a voice Assistants Siri and Alexa.

• Touch - Based Interaction :-

- Touchscreen's enable directly manipulation of a elements, make interactions more facile and intuitive.

• Gesture - Based Interaction :-

- Motion and gesture, it provides users pinching, swiping, rotating them and allows a user to interacting with the System as natural-hand interaction.

• VR and AR :-

- In a VR and AR interface creates a immersive experience, allows users to interactive with the Computer in a digital Content and Spatial Content.

• Multimodal Interaction :-

- Combining multiple input and output methods such as Screen and Touch allows users to interact with the Human Computer Interaction.



90

[Signature]

(b) • Human Interaction Speeds :-

• Human Interaction Speeds is significantly depending on the Content, individuals' incomes, using Complexity of time.

- Typing Speeds
- Reaction Time
- Speech Speed/Rate
- Reading Speed
- Gesture Recognition
- Hand-eye Co-ordination
- Decision making
- Multitasking

• Type Speeds :-

• The average type speed for the individual person is about 40 and 60 Words per minute.

• On Computer keyboard Skilled typists speed is about 80 words per minute.

• Reaction Time :-

• Human Reaction Time is about 200 to 300 milliseconds in the simple task, they are responses in the visual stimuli.



- These are based on the age, attention and other factors.

• Speech Rate :-

- The avg speaking rate and conversational speech speed is about 150 to 160 per minute.
- These are based on the speech pace and language complexity.

• Reading Speed :-

- Reading speed is very, but the average reading speed is about 200 to 300 words per minute for the adults.
- With Comprehension Speed trade-off.

• Gesture Recognition :-

- Human gesture recognition is swift with the people recognition and therefore common gestures almost instant.

• Hand-eye Co-ordination :-

- Human Hand-eye Coordination allows users for rapid responses, such as catch a ball and performing tasks like drawings.

• Decision making :-

- The speed of decision making varies based on the complexity of the decision.

• Multitasking :-

- Human multitasking is a myth, but its generally acknowledged and shifting blue-tasks.

4. (a) • Goals of Screen Designing :-

- Designing of the process special objectives that aims and guide the process is created by a product, system and interface.

• User-Centrical Design

• ~~Functionality~~

• Usability

• Efficiency

• Feedback Communication

• Visual Appealing

• ~~Efficiency~~

• Innovation and Creativity

• Emotional Connection

• Consistency



• Interaction :-

- Computers are highly interaction with the users, and that manner is said to be in a user-device.

• Visual Hierarchy :-

- A users can view anything in a hierarchy way.



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MCA

HTNO	SUBJECT	refCode	SM	MID I	SM	MID II	FF	SST	I	TOTAL	SUB TYPE
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23H41F0003	23MC2T07	23MC2T07	27	27	27	27	-	-	-	27.0	T
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23H41F0033	23MC2T07	23MC2T07	21	21	26	26	-	-	-	25.0	T
23H41F0034	23MC2T07	23MC2T07	21	21	29	29	-	-	-	28.0	T
23H41F0035	23MC2T07	23MC2T07	19	19	29	29	-	-	-	27.0	T
23H41F0036	23MC2T07	23MC2T07	17	17	24	24	-	-	-	23.0	T
23H41F0037	23MC2T07	23MC2T07	26	26	24	24	-	-	-	26.0	T
23H41F0038	23MC2T07	23MC2T07	29	29	23	23	-	-	-	28.0	T
23H41F0039	23MC2T07	23MC2T07	29	29	27	27	-	-	-	29.0	T
23H41F0040	23MC2T07	23MC2T07	21	21	25	25	-	-	-	25.0	T
23H41F0041	23MC2T07	23MC2T07	20	20	29	29	-	-	-	28.0	T
23H41F0042	23MC2T07	23MC2T07	29	29	30	30	-	-	-	30.0	T
23H41F0043	23MC2T07	23MC2T07	27	27	24	24	-	-	-	27.0	T
23H41F0044	23MC2T07	23MC2T07	29	29	26	26	-	-	-	29.0	T

2311411 0001	2350 2101	2350 2101	28	28	27	28	-	-	-	28.0	T
2311411 0005	2350 2101	2350 2101	28	30	29	29	-	-	-	28.0	T
2311411 0006	2350 2101	2350 2101	30	30	30	30	-	-	-	30.0	T
2311411 0007	2350 2101	2350 2101	30	30	30	30	-	-	-	30.0	T
2311411 0008	2350 2101	2350 2101	30	30	30	30	-	-	-	30.0	T
2311411 0009	2350 2101	2350 2101	28	28	28	28	-	-	-	28.0	T
2311411 0090	2350 2101	2350 2101	29	29	29	29	-	-	-	29.0	T
2311411 0091	2350 2101	2350 2101	28	28	25	25	-	-	-	28.0	T
2311411 0092	2350 2101	2350 2101	-	-	-	-	-	-	-	0.0	T
2311411 0093	2350 2101	2350 2101	28	28	27	27	-	-	-	28.0	T
2311411 0094	2350 2101	2350 2101	29	29	28	28	-	-	-	29.0	T
2311411 0095	2350 2101	2350 2101	30	30	30	30	-	-	-	30.0	T
2311411 0001	2350 2108	2350 2108	29	29	28	28	-	-	-	29.0	T
2311411 0002	2350 2108	2350 2108	28	28	28	28	-	-	-	28.0	T
2311411 0003	2350 2108	2350 2108	27	27	27	27	-	-	-	27.0	T
2311411 0004	2350 2108	2350 2108	27	27	27	27	-	-	-	27.0	T
2311411 0005	2350 2108	2350 2108	24	24	24	24	-	-	-	24.0	T
2311411 0006	2350 2108	2350 2108	27	27	27	27	-	-	-	27.0	T
2311411 0007	2350 2108	2350 2108	28	28	27	27	-	-	-	28.0	T
2311411 0008	2350 2108	2350 2108	28	28	28	28	-	-	-	28.0	T
2311411 0009	2350 2108	2350 2108	28	28	28	28	-	-	-	28.0	T
2311411 0010	2350 2108	2350 2108	26	26	29	29	-	-	-	29.0	T
2311411 0011	2350 2108	2350 2108	27	27	29	29	-	-	-	29.0	T
2311411 0012	2350 2108	2350 2108	28	28	28	28	-	-	-	28.0	T
2311411 0013	2350 2108	2350 2108	23	23	27	27	-	-	-	27.0	T
2311411 0014	2350 2108	2350 2108	29	29	29	29	-	-	-	29.0	T
2311411 0015	2350 2108	2350 2108	28	28	28	28	-	-	-	28.0	T
2311411 0016	2350 2108	2350 2108	27	27	27	27	-	-	-	27.0	T
2311411 0017	2350 2108	2350 2108	27	27	27	27	-	-	-	27.0	T
2311411 0018	2350 2108	2350 2108	27	27	28	28	-	-	-	28.0	T
2311411 0019	2350 2108	2350 2108	27	27	29	29	-	-	-	29.0	T
2311411 0020	2350 2108	2350 2108	28	28	29	29	-	-	-	29.0	T
2311411 0021	2350 2108	2350 2108	28	28	29	29	-	-	-	29.0	T
2311411 0022	2350 2108	2350 2108	29	29	28	28	-	-	-	29.0	T
2311411 0023	2350 2108	2350 2108	28	28	28	28	-	-	-	28.0	T
2311411 0024	2350 2108	2350 2108	29	29	29	29	-	-	-	29.0	T
2311411 0025	2350 2108	2350 2108	27	27	27	27	-	-	-	27.0	T
2311411 0026	2350 2108	2350 2108	28	28	27	27	-	-	-	28.0	T
2311411 0027	2350 2108	2350 2108	29	29	28	28	-	-	-	29.0	T
2311411 0028	2350 2108	2350 2108	25	25	20	20	-	-	-	24.0	T
2311411 0029	2350 2108	2350 2108	27	27	28	28	-	-	-	28.0	T
2311411 0030	2350 2108	2350 2108	28	28	28	28	-	-	-	28.0	T
2311411 0031	2350 2108	2350 2108	28	28	28	28	-	-	-	28.0	T
2311411 0032	2350 2108	2350 2108	27	27	29	29	-	-	-	29.0	T
2311411 0033	2350 2108	2350 2108	27	27	27	27	-	-	-	27.0	T
2311411 0034	2350 2108	2350 2108	27	27	29	29	-	-	-	29.0	T
2311411 0035	2350 2108	2350 2108	23	23	28	28	-	-	-	27.0	T
2311411 0036	2350 2108	2350 2108	27	27	28	28	-	-	-	28.0	T
2311411 0037	2350 2108	2350 2108	28	28	27	27	-	-	-	28.0	T
2311411 0038	2350 2108	2350 2108	27	27	28	28	-	-	-	28.0	T
2311411 0039	2350 2108	2350 2108	27	27	29	29	-	-	-	29.0	T
2311411 0040	2350 2108	2350 2108	27	27	28	28	-	-	-	28.0	T
2311411 0041	2350 2108	2350 2108	27	27	29	29	-	-	-	29.0	T
2311411 0042	2350 2108	2350 2108	27	27	29	29	-	-	-	29.0	T
2311411 0043	2350 2108	2350 2108	28	28	29	29	-	-	-	29.0	T
2311411 0044	2350 2108	2350 2108	30	30	29	29	-	-	-	30.0	T

5	21MC2100	DESIGN AND ANALYSIS OF ALGORITHMS	1
6	21MC2101	EMLOYABILITY SKILLS	(2)
7	21MC2103	HUMAN COMPUTER INTERACTION	BSC 2101
8	21MC2106	PYTHON PROGRAMMING LAB	
9	21MC2108	SOFTWARE ENGINEERING AND DESIGN PATTERNS	2/2
10	21MC2105	SOFTWARE ENGINEERING AND DESIGN PATTERNS LAB	1/2

DATE: 18/11/21
HOD

Controller of Examinations
18/11/21

Principal
30/11/2021



Principal
BVC Institute of Technology & Science
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